SII Semiconductor Corporation

S-8211C Series

BATTERY PROTECTION IC FOR 1-CELL PACK

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The S-8211C Series is a protection IC for 1-cell lithium-ion / lithium polymer rechargeable battery and includes highaccuracy voltage detection circuits and delay circuits.

The S-8211C Series is suitable for protecting 1-cell lithium-ion / lithium polymer rechargeable battery packs from overcharge, overdischarge, and overcurrent.

Features

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 High-accuracy voltage detection circuit 		
Overcharge detection voltage	3.9 V to 4.5 V (5 mV step)	Accuracy $\pm 25 \text{ mV}$ (Ta = $\pm 25^{\circ}$ C)
		Accuracy $\pm 30 \text{ mV}$ (Ta = -5°C to $+55^{\circ}\text{C}$)
Overcharge release voltage	3.8 V to 4.43 V*1	Accuracy ±50 mV
Overdischarge detection voltage	2.0 V to 3.0 V (10 mV step)	Accuracy ±50 mV
Overdischarge release voltage	2.0 V to 3.4 V*2	Accuracy ±100 mV
Discharge overcurrent detection voltage	0.05 V to 0.30 V (10 mV step)	Accuracy ±15 mV
Load short-circuiting detection voltage	0.5 V (fixed)	Accuracy ±200 mV
Charge overcurrent detection voltage	–0.1 V (fixed)	Accuracy ±30 mV
Detection delay times are generated only by an	internal circuit (external capaci	tors are unnecessary).
		Accuracy ±20%
High-withstand voltage (VM pin and CO pin: Ab	osolute maximum rating = 28 V)	
0 V battery charge function "available" / "unava	ilable" is selectable.	
 Power-down function "available" / "unavailable" 	' is selectable.	
 Wide operation temperature range 	Ta = -40°C to +85°C	
 Low current consumption 		
During operation	3.0 μA typ., 5.5 μA max. (Ta =	• +25°C)
During power-down	0.2 μA max. (Ta = +25°C)	

- Lead-free, Sn 100%, halogen-free*3
- *1. Overcharge release voltage = Overcharge detection voltage Overcharge hysteresis voltage (Overcharge hysteresis voltage can be selected as 0 V or from a range of 0.1 V to 0.4 V in 50 mV step.)
- *2. Overdischarge release voltage = Overdischarge detection voltage + Overdischarge hysteresis voltage
- (Overdischarge hysteresis voltage can be selected as 0 V or from a range of 0.1 V to 0.7 V in 100 mV step.) *3. Refer to "■ Product Name Structure" for details.

Applications

- · Lithium-ion rechargeable battery pack
- Lithium polymer rechargeable battery pack

Packages

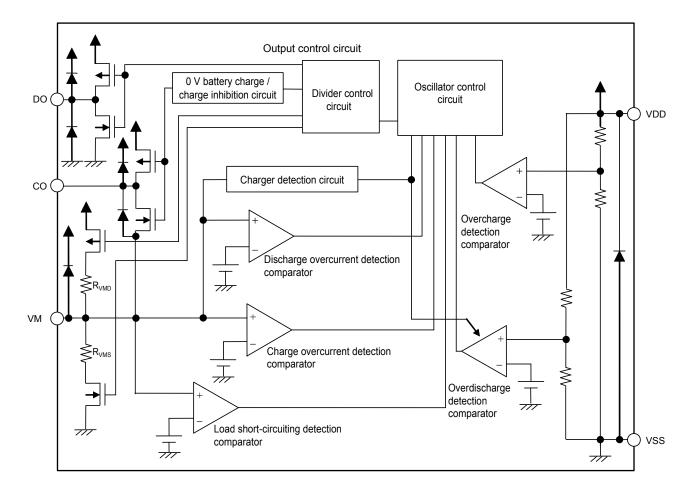
- SOT-23-5
- SNT-6A



Rev.7.7_02

1

Block Diagram

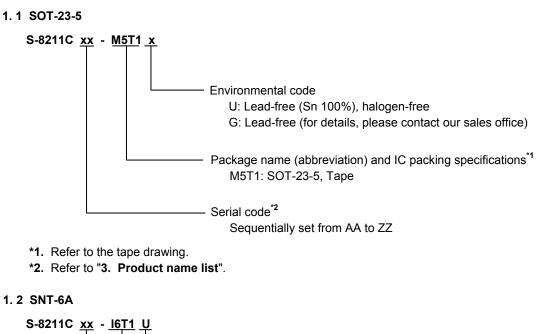


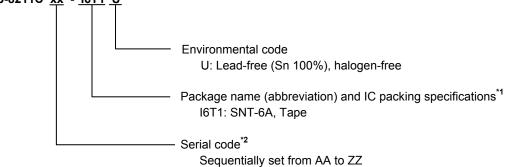
Remark All diodes shown in figure are parasitic diodes.

Figure 1

Product Name Structure

1. Product name





- ***1.** Refer to the tape drawing.
- *2. Refer to "3. Product name list".

2. Packages

Table 1 Package Drawing Codes

Package Name	Dimension	Таре	Reel	Land
SOT-23-5	MP005-A-P-SD	MP005-A-C-SD	MP005-A-R-SD	_
SNT-6A	PG006-A-P-SD	PG006-A-C-SD	PG006-A-R-SD	PG006-A-L-SD

3. Product name list

3.1 SOT-23-5

Product Name charge Detection Voltage charge Voltage charge Voltage Overcirent Voltage V Battery Voltage Delevition Voltage Delevition Volta		-	-	-	-	.			
Product Name Detection Voitage Release Voitage Detection Voitage Release Voitage Detection Voitage Charge Voitage Detection Voitage Charge Voitage Detection Voitage Charge Voitage Detection Voitage Charge Voitage Detection Voitage Detection Voit		Over-	Over-	Over-	Over-	Discharge			
Product Name Defection Release Voltage Unitiant Charge Function Combination*1 Function S-8211CAA-MST1x 4.275 V 4.175 V 2.30 V 2.40 V 0.10 V Available (1) Available (2) Available (2) Available (2) Available (2) Available (3) Available (3) Available (3) Available (4) Available (5) Available (5) Available (5) Available (5) Available (4) Available (4) </td <td></td> <td>-</td> <td>-</td> <td>-</td> <td>-</td> <td></td> <td></td> <td>Delay Time</td> <td>Power-down</td>		-	-	-	-			Delay Time	Power-down
[Va.] [Va.] <th< td=""><td>Product Name</td><td></td><td></td><td></td><td></td><td></td><td>-</td><td>•</td><td>Function</td></th<>	Product Name						-	•	Function
S-8211CAA-M5T1x 4.275 V 4.175 V 2.30 V 2.40 V 0.10 V Available (1) Available S-8211CAB-M5T1x 4.325 V 4.075 V 2.50 V 2.90 V 0.15 V Available (2) Available S-8211CAE-M5T1x 4.350 V 4.160 V 2.30 V 2.30 V 0.20 V Available (3) Available S-8211CAE-M5T1x 4.280 V 4.160 V 2.30 V 2.30 V 0.10 V Available (5) Available S-8211CAH-M5T1x 4.280 V 4.080 V 2.30 V 2.30 V 0.10 V Available (1) Available S-8211CAH-M5T1x 4.280 V 4.080 V 2.30 V 2.30 V 0.10 V Available (1) Available S-8211CAK-M5T1x 4.280 V 4.080 V 2.30 V 2.30 V 0.13 V Unavailable (1) Available S-8211CAK-M5T1x 4.280 V 4.130 V 2.60 V 3.10 V 0.15 V Unavailable (1) Available S-8211CAK-M5T1x		-	-	-	-	-	Function		
S-8211CAB-M5T1x 4.325 V 4.075 V 2.50 V 2.90 V 0.15 V Unavailable (2) Available S-8211CAD-M5T1x 4.350 V 4.150 V 2.30 V 3.00 V 0.20 V Available (3) Available S-8211CAF-M5T1x 4.275 V 4.275 V 2.30 V 2.30 V 0.12 V Available (1) Available S-8211CAF-M5T1x 4.280 V 4.080 V 2.30 V 2.30 V 0.08 V Available (1) Available S-8211CAF-M5T1x 4.280 V 4.080 V 2.30 V 2.30 V 0.10 V Available (1) Available S-8211CAF-M5T1x 4.280 V 4.080 V 2.30 V 2.30 V 0.10 V Available (1) Available S-8211CAF-M5T1x 4.280 V 4.130 V 2.80 V 3.10 V 0.15 V Unavailable (1) Available S-8211CAF-M5T1x 4.280 V 4.130 V 2.80 V 3.10 V 0.15 V Unavailable (1) Available S-8211CAF-M5T1x								(1)	
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S-8211CAT-M5T1x 4.275 V 4.075 V 2.80 V 3.10 V 0.10 V Available (4) Available S-8211CAU-M5T1x 4.280 V 4.130 V 2.80 V 3.10 V 0.05 V Unavailable (1) Available S-8211CAV-M5T1x 4.325 V 4.075 V 2.50 V 2.90 V 0.15 V Available (2) Available S-8211CAV-M5T1x 4.280 V 4.280 V 2.80 V 2.80 V 0.05 V Available (1) Available S-8211CAV-M5T1x 4.280 V 4.280 V 2.80 V 2.80 V 0.075 V Available (1) Available S-8211CAV-M5T1x 4.280 V 4.080 V 2.80 V 2.80 V 0.15 V Available (1) Available S-8211CD-M5T1U 4.280 V 4.080 V 2.80 V 2.80 V 0.15 V Available (1) Available S-8211CCD-M5T1U 4.280 V 4.130 V 2.70 V 3.10 V 0.20 V Available (1) Available S-8211CCD-M5T1U	S-8211CAR-M5T1x	4.275 V	4.075 V	2.30 V	2.30 V	0.15 V	Available	(1)	Available
S-8211CAU-M5T1x 4.280 V 4.130 V 2.80 V 3.10 V 0.05 V Unavailable (1) Available S-8211CAV-M5T1x 4.325 V 4.075 V 2.50 V 2.90 V 0.15 V Available (2) Available S-8211CAV-M5T1x 4.280 V 2.80 V 2.80 V 0.05 V Available (1) Available S-8211CAZ-M5T1x 4.280 V 4.280 V 2.80 V 0.075 V Available (1) Available S-8211CAZ-M5T1x 4.280 V 4.280 V 2.80 V 0.075 V Available (1) Available S-8211CAD-M5T1x 4.280 V 4.080 V 2.80 V 0.15 V Available (1) Available S-8211CCD-M5T1U 4.280 V 4.080 V 2.80 V 0.15 V Available (1) Available S-8211CCD-M5T1U 4.280 V 4.130 V 2.70 V 3.10 V 0.20 V Available (1) Available S-8211CCJ-M5T1U 4.250 V 4.050 V 2.10 V 2.20 V 0.30 V Unavailable (1) Available S-8211CCC-M5T1U 4.350 V <td>S-8211CAS-M5T1x</td> <td>4.280 V</td> <td>4.130 V</td> <td>2.80 V</td> <td>3.10 V</td> <td>0.10 V</td> <td>Unavailable</td> <td>(1)</td> <td>Available</td>	S-8211CAS-M5T1x	4.280 V	4.130 V	2.80 V	3.10 V	0.10 V	Unavailable	(1)	Available
S-8211CAV-M5T1x 4.325 V 4.075 V 2.50 V 2.90 V 0.15 V Available (2) Available S-8211CAY-M5T1x 4.280 V 4.280 V 2.80 V 2.80 V 0.05 V Available (1) Available S-8211CAZ-M5T1x 4.280 V 4.280 V 3.00 V 3.00 V 0.075 V Available (1) Available S-8211CAZ-M5T1x 4.280 V 4.080 V 2.80 V 2.80 V 0.075 V Available (1) Available S-8211CD-M5T1x 4.280 V 4.080 V 2.80 V 2.80 V 0.15 V Available (1) Available S-8211CCD-M5T1U 4.280 V 4.130 V 2.70 V 3.10 V 0.20 V Available (1) Available S-8211CCJ-M5T1U*/ 4.250 V 4.025 V 2.50 V 2.90 V 0.15 V Available (1) Available S-8211CCC-M5T1U 4.350 V 4.150 V 2.10 V 2.20 V 0.30 V Unavailable (1) Available S-8211CCC-M5T1U	S-8211CAT-M5T1x	4.275 V	4.075 V	2.80 V	3.10 V	0.10 V	Available	(4)	Available
S-8211CAY-M5T1x 4.280 V 4.280 V 2.80 V 2.80 V 0.05 V Available (1) Available S-8211CAZ-M5T1x 4.280 V 4.280 V 3.00 V 3.00 V 0.075 V Available (1) Available S-8211CBV-M5T1x 4.280 V 4.080 V 2.80 V 2.80 V 0.15 V Available (4) Available S-8211CDV-M5T1U 4.280 V 4.130 V 2.70 V 3.10 V 0.20 V Available (1) Available S-8211CCJ-M5T1U*// 4.225 V 4.025 V 2.50 V 2.90 V 0.15 V Available (1) Available S-8211CCV-M5T1U 4.350 V 4.150 V 2.10 V 2.90 V 0.15 V Available (1) Available S-8211CCV-M5T1U 4.350 V 4.150 V 2.10 V 2.20 V 0.30 V Unavailable (1) Available S-8211CCP-M5T1U 4.350 V 4.150 V 2.10 V 2.20 V 0.15 V Unavailable (1) Available S-8211CCR-M5T1U	S-8211CAU-M5T1x	4.280 V	4.130 V	2.80 V	3.10 V	0.05 V	Unavailable	(1)	Available
S-8211CAY-M5T1x 4.280 V 4.280 V 2.80 V 2.80 V 0.05 V Available (1) Available S-8211CAZ-M5T1x 4.280 V 4.280 V 3.00 V 3.00 V 0.075 V Available (1) Available S-8211CBV-M5T1x 4.280 V 4.080 V 2.80 V 2.80 V 0.15 V Available (4) Available S-8211CDV-M5T1U 4.280 V 4.130 V 2.70 V 3.10 V 0.20 V Available (1) Available S-8211CCJ-M5T1U*// 4.225 V 4.025 V 2.50 V 2.90 V 0.15 V Available (1) Available S-8211CCV-M5T1U 4.350 V 4.150 V 2.10 V 2.90 V 0.15 V Available (1) Available S-8211CCV-M5T1U 4.350 V 4.150 V 2.10 V 2.20 V 0.30 V Unavailable (1) Available S-8211CCP-M5T1U 4.350 V 4.150 V 2.10 V 2.20 V 0.15 V Unavailable (1) Available S-8211CCR-M5T1U	S-8211CAV-M5T1x	4.325 V	4.075 V	2.50 V	2.90 V	0.15 V	Available	(2)	Available
S-8211CBV-M5T1x 4.280 V 4.080 V 2.80 V 2.80 V 0.15 V Available (4) Available S-8211CCD-M5T1U 4.280 V 4.130 V 2.70 V 3.10 V 0.20 V Available (1) Available S-8211CCJ-M5T1U*2 4.225 V 4.025 V 2.50 V 2.90 V 0.15 V Available (8) Unavailable S-8211CCK-M5T1U 4.350 V 4.150 V 2.10 V 2.20 V 0.30 V Unavailable (1) Available S-8211CCQ-M5T1U 4.350 V 4.150 V 2.10 V 2.20 V 0.30 V Unavailable (1) Available S-8211CCQ-M5T1U 4.350 V 4.150 V 2.10 V 2.20 V 0.12 V Unavailable (1) Available S-8211CCR-M5T1U 4.350 V 4.150 V 2.10 V 2.20 V 0.15 V Unavailable (1) Available S-8211CCR-M5T1U 4.250 V 2.10 V 2.20 V 0.15 V Unavailable (1) Available S-8211CCV-M5T1U 4.220 V 4.150 V 2.50 V 2.80 V 0.16 V Available (1)		4.280 V	4.280 V	2.80 V	2.80 V	0.05 V	Available		Available
S-8211CCD-M5T1U 4.280 V 4.130 V 2.70 V 3.10 V 0.20 V Available (1) Available S-8211CCJ-M5T1U*2 4.225 V 4.025 V 2.50 V 2.90 V 0.15 V Available (8) Unavailable S-8211CCJ-M5T1U*2 4.225 V 4.025 V 2.50 V 2.90 V 0.15 V Available (8) Unavailable S-8211CCK-M5T1U 4.350 V 4.150 V 2.10 V 2.20 V 0.30 V Unavailable (1) Available S-8211CCQ-M5T1U 4.350 V 4.150 V 2.10 V 2.20 V 0.12 V Unavailable (1) Available S-8211CCR-M5T1U 4.350 V 4.150 V 2.10 V 2.20 V 0.15 V Unavailable (1) Available S-8211CCR-M5T1U 4.350 V 4.150 V 2.50 V 2.80 V 0.16 V Available (1) Available S-8211CCV-M5T1U 4.220 V 4.120 V 2.50 V 2.80 V 0.16 V Available (3) Available S-8211CCV-M5T1U </td <td>S-8211CAZ-M5T1x</td> <td>4.280 V</td> <td>4.280 V</td> <td>3.00 V</td> <td>3.00 V</td> <td>0.075 V</td> <td>Available</td> <td>(1)</td> <td>Available</td>	S-8211CAZ-M5T1x	4.280 V	4.280 V	3.00 V	3.00 V	0.075 V	Available	(1)	Available
S-8211CCJ-M5T1U*2 4.225 V 4.025 V 2.50 V 2.90 V 0.15 V Available (8) Unavailable S-8211CCK-M5T1U 4.350 V 4.150 V 2.10 V 2.20 V 0.30 V Unavailable (1) Available S-8211CCQ-M5T1U 4.350 V 4.150 V 2.10 V 2.20 V 0.12 V Unavailable (1) Available S-8211CCQ-M5T1U 4.350 V 4.150 V 2.10 V 2.20 V 0.12 V Unavailable (1) Available S-8211CCR-M5T1U 4.350 V 4.150 V 2.10 V 2.20 V 0.15 V Unavailable (1) Available S-8211CCR-M5T1U 4.350 V 4.150 V 2.50 V 2.80 V 0.16 V Available (1) Available S-8211CCV-M5T1U 4.220 V 4.120 V 2.50 V 2.80 V 0.16 V Available (1) Unavailable S-8211CCV-M5T1U 4.280 V 4.130 V 2.30 V 3.00 V 0.20 V Available (3) Available S-8211CDB-M5T1U 4.100 V 3.850 V 2.50 V 2.90 V 0.15 V Unavailabl			4.080 V	2.80 V	2.80 V	0.15 V	Available	(4)	
S-8211CCJ-M5T1U*2 4.225 V 4.025 V 2.50 V 2.90 V 0.15 V Available (8) Unavailable S-8211CCK-M5T1U 4.350 V 4.150 V 2.10 V 2.20 V 0.30 V Unavailable (1) Available S-8211CCQ-M5T1U 4.350 V 4.150 V 2.10 V 2.20 V 0.12 V Unavailable (1) Available S-8211CCQ-M5T1U 4.350 V 4.150 V 2.10 V 2.20 V 0.12 V Unavailable (1) Available S-8211CCR-M5T1U 4.350 V 4.150 V 2.10 V 2.20 V 0.15 V Unavailable (1) Available S-8211CCR-M5T1U 4.350 V 4.150 V 2.50 V 2.80 V 0.16 V Available (1) Available S-8211CCV-M5T1U 4.220 V 4.120 V 2.50 V 2.80 V 0.16 V Available (1) Unavailable S-8211CCV-M5T1U 4.280 V 4.130 V 2.30 V 3.00 V 0.20 V Available (3) Available S-8211CDB-M5T1U 4.100 V 3.850 V 2.50 V 2.90 V 0.15 V Unavailabl	S-8211CCD-M5T1U	4.280 V	4.130 V	2.70 V	3.10 V	0.20 V	Available	(1)	Available
S-8211CCK-M5T1U 4.350 V 4.150 V 2.10 V 2.20 V 0.30 V Unavailable (1) Available S-8211CCQ-M5T1U 4.350 V 4.150 V 2.10 V 2.20 V 0.12 V Unavailable (1) Available S-8211CCQ-M5T1U 4.350 V 4.150 V 2.10 V 2.20 V 0.12 V Unavailable (1) Available S-8211CCR-M5T1U 4.350 V 4.150 V 2.10 V 2.20 V 0.15 V Unavailable (1) Available S-8211CCT-M5T1U 4.150 V 4.050 V 2.50 V 2.80 V 0.16 V Available (1) Available S-8211CCV-M5T1U 4.220 V 4.120 V 2.50 V 2.80 V 0.16 V Available (1) Unavailable S-8211CCW-M5T1U 4.280 V 4.130 V 2.30 V 3.00 V 0.20 V Available (3) Available S-8211CDB-M5T1U 4.100 V 3.850 V 2.50 V 2.90 V 0.15 V Unavailable (1) Available S-8211CDB-M5T1U <td></td> <td></td> <td></td> <td></td> <td></td> <td></td> <td>Available</td> <td></td> <td></td>							Available		
S-8211CCQ-M5T1U 4.350 V 4.150 V 2.10 V 2.20 V 0.12 V Unavailable (1) Available S-8211CCR-M5T1U 4.350 V 4.150 V 2.10 V 2.20 V 0.15 V Unavailable (1) Available S-8211CCR-M5T1U 4.350 V 4.150 V 2.50 V 2.80 V 0.16 V Available (1) Available S-8211CCV-M5T1U 4.120 V 2.50 V 2.80 V 0.16 V Available (1) Unavailable S-8211CCV-M5T1U 4.220 V 4.120 V 2.50 V 2.80 V 0.16 V Available (1) Unavailable S-8211CCW-M5T1U 4.220 V 4.130 V 2.30 V 3.00 V 0.20 V Available (3) Available S-8211CDB-M5T1U 4.100 V 3.850 V 2.50 V 2.90 V 0.15 V Unavailable (1) Available S-8211CDD-M5T1U 4.150 V 2.10 V 2.20 V 0.12 V Unavailable (6) Available S-8211CDG-M5T1U 4.275 V 4.075 V <td>S-8211CCK-M5T1U</td> <td></td> <td></td> <td></td> <td>2.20 V</td> <td>0.30 V</td> <td>Unavailable</td> <td>(1)</td> <td>Available</td>	S-8211CCK-M5T1U				2.20 V	0.30 V	Unavailable	(1)	Available
S-8211CCT-M5T1U 4.150 V 4.050 V 2.50 V 2.80 V 0.16 V Available (1) Available S-8211CCV-M5T1U 4.220 V 4.120 V 2.50 V 2.80 V 0.16 V Available (1) Unavailable S-8211CCV-M5T1U 4.220 V 4.120 V 2.50 V 2.80 V 0.16 V Available (1) Unavailable S-8211CCW-M5T1U 4.280 V 4.130 V 2.30 V 3.00 V 0.20 V Available (3) Available S-8211CDB-M5T1U 4.100 V 3.850 V 2.50 V 2.90 V 0.15 V Unavailable (1) Available S-8211CDD-M5T1U 4.350 V 4.150 V 2.10 V 2.20 V 0.12 V Unavailable (6) Available S-8211CDG-M5T1U 4.275 V 4.075 V 2.50 V 3.00 V 0.16 V Available (1) Available S-8211CDJ-M5T1U 4.275 V 4.075 V 2.50 V 3.00 V 0.16 V Available (1) Available S-8211CDJ-M5T1U							Unavailable	(1)	
S-8211CCT-M5T1U 4.150 V 4.050 V 2.50 V 2.80 V 0.16 V Available (1) Available S-8211CCV-M5T1U 4.220 V 4.120 V 2.50 V 2.80 V 0.16 V Available (1) Unavailable S-8211CCV-M5T1U 4.220 V 4.120 V 2.50 V 2.80 V 0.16 V Available (1) Unavailable S-8211CCW-M5T1U 4.280 V 4.130 V 2.30 V 3.00 V 0.20 V Available (3) Available S-8211CDB-M5T1U 4.100 V 3.850 V 2.50 V 2.90 V 0.15 V Unavailable (1) Available S-8211CDD-M5T1U 4.350 V 4.150 V 2.10 V 2.20 V 0.12 V Unavailable (6) Available S-8211CDG-M5T1U 4.275 V 4.075 V 2.50 V 3.00 V 0.16 V Available (1) Available S-8211CDJ-M5T1U 4.275 V 4.075 V 2.50 V 3.00 V 0.16 V Available (1) Available S-8211CDJ-M5T1U		4.350 V						(1)	
S-8211CCV-M5T1U 4.220 V 4.120 V 2.50 V 2.80 V 0.16 V Available (1) Unavailable S-8211CCW-M5T1U 4.280 V 4.130 V 2.30 V 3.00 V 0.20 V Available (3) Available S-8211CDB-M5T1U 4.100 V 3.850 V 2.50 V 2.90 V 0.15 V Unavailable (1) Available S-8211CDD-M5T1U 4.150 V 2.10 V 2.20 V 0.12 V Unavailable (6) Available S-8211CDG-M5T1U 4.275 V 4.075 V 2.50 V 3.00 V 0.16 V Available (1) Available S-8211CDG-M5T1U 4.275 V 4.075 V 2.50 V 3.00 V 0.16 V Available (1) Available S-8211CDG-M5T1U 4.250 V 2.90 V 3.00 V 0.16 V Available (1) Available S-8211CDJ-M5T1U 4.150 V 2.90 V 3.00 V 0.15 V Unavailable (1) Available									
S-8211CCW-M5T1U 4.280 V 4.130 V 2.30 V 3.00 V 0.20 V Available (3) Available S-8211CDB-M5T1U 4.100 V 3.850 V 2.50 V 2.90 V 0.15 V Unavailable (1) Available S-8211CDD-M5T1U 4.350 V 4.150 V 2.10 V 2.20 V 0.12 V Unavailable (6) Available S-8211CDG-M5T1U 4.275 V 4.075 V 2.50 V 3.00 V 0.16 V Available (1) Available S-8211CDJ-M5T1U 4.275 V 4.075 V 2.50 V 3.00 V 0.16 V Available (1) Available S-8211CDJ-M5T1U 4.150 V 2.90 V 3.00 V 0.15 V Unavailable (1) Available							Available		
S-8211CDB-M5T1U 4.100 V 3.850 V 2.50 V 2.90 V 0.15 V Unavailable (1) Available S-8211CDD-M5T1U 4.350 V 4.150 V 2.10 V 2.20 V 0.12 V Unavailable (6) Available S-8211CDG-M5T1U 4.275 V 4.075 V 2.50 V 3.00 V 0.16 V Available (1) Available S-8211CDG-M5T1U 4.275 V 4.075 V 2.50 V 3.00 V 0.16 V Available (1) Available S-8211CDJ-M5T1U 4.150 V 4.050 V 2.90 V 3.00 V 0.15 V Unavailable (1) Available									
S-8211CDD-M5T1U 4.350 V 4.150 V 2.10 V 2.20 V 0.12 V Unavailable (6) Available S-8211CDG-M5T1U 4.275 V 4.075 V 2.50 V 3.00 V 0.16 V Available (1) Available S-8211CDJ-M5T1U 4.150 V 4.050 V 2.90 V 3.00 V 0.15 V Unavailable (1) Available									
S-8211CDG-M5T1U 4.275 V 4.075 V 2.50 V 3.00 V 0.16 V Available (1) Available S-8211CDJ-M5T1U 4.150 V 4.050 V 2.90 V 3.00 V 0.15 V Unavailable (1) Available									
S-8211CDJ-M5T1U 4.150 V 4.050 V 2.90 V 3.00 V 0.15 V Unavailable (1) Available									
	S-8211CDN-M5T1U	4.350 V	4.150 V	2.80 V	3.10 V	0.05 V	Available	(1)	Available

Table 2

*1. Refer to Table 4 about the details of the delay time combinations.

*2. The charge overcurrent detection voltage: –0.15 V \pm 0.03 V (Ta = +25°C)

Remark 1. Please contact our sales office for the products with detection voltage value other than those specified above.2. x: G or U

3. Please select products of environmental code = U for Sn 100%, halogen-free products.

Rev.7.7_02

BATTERY PROTECTION IC FOR 1-CELL PACK S-8211C Series

3.2 SNT-6A

	Over-	Over-	Over-	Over-	Discharge						
	charge	charge	discharge	discharge	Overcurrent	0 V Battery	Delay Time	Power-down			
Product Name	Detection	Release	Detection	Release	Detection	Charge	Combination ^{*1}	Function			
	Voltage	Voltage	Voltage	Voltage	Voltage	Function	Combination	T UTICUOT			
	[Vcu]	[Vcl]	[Vdl]	[V _{DU}]	[V _{DIOV}]						
S-8211CAA-I6T1U	4.275 V	4.175 V	2.30 V	2.40 V	0.10 V	Available	(1)	Available			
S-8211CAB-I6T1U	4.325 V	4.075 V	2.50 V	2.90 V	0.15 V	Unavailable	(2)	Available			
S-8211CAD-I6T1U	4.350 V	4.150 V	2.30 V	3.00 V	0.20 V	Available	(3)	Available			
S-8211CAE-I6T1U	4.280 V	4.180 V	2.30 V	2.30 V	0.12 V	Available	(4)	Available			
S-8211CAF-I6T1U	4.275 V	4.275 V	2.30 V	2.30 V	0.10 V	Available	(5)	Available			
S-8211CAH-I6T1U	4.280 V	4.080 V	2.30 V	2.30 V	0.08 V	Available	(1)	Available			
S-8211CAI-I6T1U	4.280 V	4.080 V	2.30 V	2.30 V	0.10 V	Available	(1)	Available			
S-8211CAJ-I6T1U	4.280 V	4.080 V	2.30 V	2.30 V	0.10 V	Unavailable	(1)	Available			
S-8211CAK-I6T1U	4.280 V	4.080 V	2.30 V	2.30 V	0.13 V	Unavailable	(1)	Available			
S-8211CAL-I6T1U	4.280 V	4.130 V	2.60 V	3.10 V	0.15 V	Unavailable	(1)	Available			
S-8211CAM-I6T1U	4.280 V	4.130 V	2.80 V	3.10 V	0.15 V	Unavailable	(1)	Available			
S-8211CAN-I6T1U	4.200 V	4.100 V	2.80 V	2.90 V	0.15 V	Unavailable	(1)	Available			
S-8211CAO-I6T1U	4.275 V	4.075 V	2.30 V	2.30 V	0.12 V	Available	(5)	Available			
S-8211CAP-I6T1U	4.275 V	4.075 V	2.30 V	2.30 V	0.13 V	Available	(5)	Available			
S-8211CAQ-I6T1U	4.275 V	4.075 V	2.30 V	2.30 V	0.15 V	Available	(5)	Available			
S-8211CAR-I6T1U	4.275 V	4.075 V	2.30 V	2.30 V	0.15 V	Available	(1)	Available			
S-8211CAS-I6T1U	4.280 V	4.130 V	2.80 V	3.10 V	0.10 V	Unavailable	(1)	Available			
S-8211CAT-I6T1U	4.275 V	4.075 V	2.80 V	3.10 V	0.10 V	Available	(4)	Available			
S-8211CAU-I6T1U	4.280 V	4.130 V	2.80 V	3.10 V	0.05 V	Unavailable	(1)	Available			
S-8211CAV-I6T1U	4.325 V	4.075 V	2.50 V	2.90 V	0.15 V	Available	(2)	Available			
S-8211CAW-I6T1U	4.280 V	4.080 V	2.40 V	2.40 V	0.05 V	Unavailable	(6)	Available			
S-8211CAX-I6T1U	4.275 V	4.175 V	2.30 V	2.30 V	0.12 V	Available	(4)	Available			
S-8211CAY-I6T1U	4.280 V	4.280 V	2.80 V	2.80 V	0.05 V	Available	(1)	Available			
S-8211CAZ-I6T1U	4.280 V	4.280 V	3.00 V	3.00 V	0.075 V	Available	(1)	Available			
S-8211CBA-I6T1U	4.275 V	4.175 V	2.30 V	2.40 V	0.05 V	Available	(1)	Available			
S-8211CBB-I6T1U	4.300 V	4.100 V	2.30 V	2.30 V	0.13 V	Available	(1)	Available			
S-8211CBD-I6T1U	4.275 V	4.275 V	2.30 V	2.30 V	0.05 V	Available	(5)	Available			
S-8211CBF-I6T1U	4.300 V	4.100 V	2.10 V	2.10 V	0.13 V	Available	(1)	Available			
S-8211CBH-I6T1U	4.275 V	4.175 V	2.80 V	2.90 V	0.08 V	Available	(1)	Available			
S-8211CBJ-I6T1U	4.275 V	4.075 V	2.80 V	2.90 V	0.10 V	Available	(5)	Available			
S-8211CBN-I6T1U	4.225 V	4.125 V	2.00 V	2.00 V	0.20 V	Unavailable	(7)	Available			
S-8211CBO-I6T1U	4.270 V	4.070 V	2.30 V	2.30 V	0.10 V	Available	(5)	Available			
S-8211CBR-I6T1U	4.280 V	4.180 V	2.30 V	2.30 V	0.12 V	Unavailable	(4)	Available			
S-8211CBV-I6T1U	4.280 V	4.080 V	2.80 V	2.80 V	0.15 V	Available	(4)	Available			
S-8211CBW-I6T1U	4.280 V	4.180 V	2.50 V	2.70 V	0.19 V	Unavailable	(1)	Available			
S-8211CBZ-I6T1U	4.375 V	4.125 V	2.50 V	2.90 V	0.12 V	Unavailable	(4)	Available			
S-8211CCB-I6T1U	4.250 V	4.050 V	3.00 V	3.20 V	0.10 V	Available	(1)	Available			
S-8211CCC-I6T1U	4.270 V	4.070 V	3.00 V	3.00 V	0.10 V	Available	(5)	Available			
S-8211CCD-I6T1U	4.280 V	4.130 V	2.70 V	3.10 V	0.20 V	Available	(1)	Available			
S-8211CCE-I6T1U*2	4.225 V	4.025 V	2.80 V	2.80 V	0.15 V	Available	(8)	Unavailable			
S-8211CCF-I6T1U	4.350 V	4.050 V	2.30 V	2.30 V	0.13 V	Available	(5)	Available			
S-8211CCG-I6T1U	4.275 V	4.075 V	2.50 V	2.70 V	0.16 V	Unavailable	(1)	Available			

Table 3 (1 / 2)

Product Name	Over-charge Detection Voltage [Vcu]	Over- charge Release Voltage [VcL]	Over- discharge Detection Voltage [V _{DL}]	Over- discharge Release Voltage [Vɒu]	Discharge Overcurrent Detection Voltage [V _{DIOV}]	0 V Battery Charge Function	Delay Time Combination ^{*1}	Power-down Function
S-8211CCH-I6T1U*2	4.275 V	4.075 V	2.80 V	2.80 V	0.15 V	Unavailable	(8)	Available
S-8211CCI-I6T1U	4.275 V	4.075 V	2.60 V	2.60 V	0.15 V	Available	(5)	Available
S-8211CCJ-I6T1U*2	4.225 V	4.025 V	2.50 V	2.90 V	0.15 V	Available	(8)	Unavailable
S-8211CCM-I6T1U	4.275 V	4.075 V	2.80 V	3.10 V	0.20 V	Available	(4)	Available
S-8211CCN-I6T1U*2	4.280 V	4.180 V	2.50 V	2.70 V	0.17 V	Unavailable	(1)	Available
S-8211CCS-I6T1U	4.425 V	4.225 V	2.30 V	2.30 V	0.165 V	Unavailable	(5)	Available
S-8211CCU-I6T1U	4.425 V	4.225 V	2.50 V	2.50 V	0.13 V	Available	(5)	Available
S-8211CCW-I6T1U	4.280 V	4.130 V	2.30 V	3.00 V	0.20 V	Available	(3)	Available
S-8211CCX-I6T1U	4.425 V	4.225 V	2.30 V	2.30 V	0.07 V	Available	(5)	Available
S-8211CCY-I6T1U	4.280 V	4.180 V	2.80 V	2.80 V	0.12 V	Unavailable	(4)	Available
S-8211CCZ-I6T1U	4.280 V	4.180 V	2.50 V	2.50 V	0.12 V	Unavailable	(4)	Available
S-8211CDA-I6T1U	4.280 V	4.130 V	2.60 V	3.10 V	0.10 V	Unavailable	(1)	Available
S-8211CDC-I6T1U	4.280 V	4.130 V	3.00 V	3.10 V	0.15 V	Unavailable	(1)	Available
S-8211CDE-I6T1U	4.425 V	4.225 V	2.50 V	2.50 V	0.10 V	Available	(5)	Available
S-8211CDF-I6T1U	4.425 V	4.225 V	2.80 V	2.80 V	0.12 V	Available	(5)	Available
S-8211CDH-I6T1U	4.275 V	4.075 V	2.60 V	2.60 V	0.10 V	Available	(5)	Available
S-8211CDI-I6T1U	4.425 V	4.225 V	2.50 V	2.50 V	0.15 V	Available	(5)	Available
S-8211CDK-I6T1U	4.425 V	4.225 V	2.50 V	2.50 V	0.15 V	Unavailable	(5)	Available
S-8211CDL-I6T1U	4.425 V	4.225 V	2.50 V	2.90 V	0.13 V	Available	(5)	Unavailable
S-8211CDM-I6T1U	4.425 V	4.225 V	2.50 V	3.10 V	0.10 V	Unavailable	(1)	Available
S-8211CDO-I6T1U	4.425 V	4.225 V	2.50 V	2.50 V	0.10 V	Unavailable	(1)	Available
S-8211CDP-I6T1U	4.425 V	4.225 V	2.50 V	2.50 V	0.13 V	Available	(9)	Available

Table 3 (2 / 2)

*1. Refer to Table 4 about the details of the delay time combinations.

*2. The charge overcurrent detection voltage: –0.15 V \pm 0.03 V (Ta = +25°C)

Remark Please contact our sales office for the products with detection voltage value other than those specified above.

BATTERY PROTECTION IC FOR 1-CELL PACK S-8211C Series

			Table 4		
Delay Time Combination	Overcharge Detection Delay Time [tcu]	Overdischarge Detection Delay Time [t _{DL}]	Discharge Overcurrent Detection Delay Time [t _{DIOV}]	Load Short-circuiting Detection Delay Time [tshort]	Charge Overcurrent Detection Delay Time [tciov]
(1)	1.2 s	150 ms	9 ms	300 μs	9 ms
(2)	1.2 s	150 ms	9 ms	560 μs	9 ms
(3)	143 ms	38 ms	18 ms	300 μs	9 ms
(4)	1.2 s	150 ms	18 ms	300 μs	9 ms
(5)	1.2 s	38 ms	9 ms	300 μs	9 ms
(6)	1.2 s	150 ms	4.5 ms	300 μs	9 ms
(7)	573 ms	150 ms	4.5 ms	300 μs	4.5 ms
(8)	1.2 s	75 ms	9 ms	300 μs	9 ms
(9)	1.2 s	300 ms	9 ms	300 μs	9 ms

Remark The delay times can be changed within the range listed in Table 5. For details, please contact our sales office.

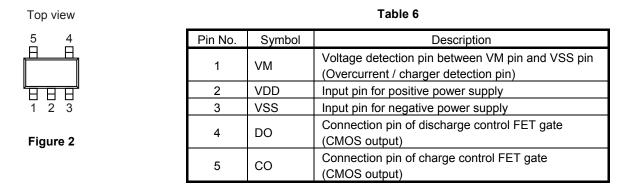
Table 5

Delay Time	Symbol		Selecti	on Range		Remark
Overcharge detection delay time	tcu	-	143 ms	573 ms	1.2 s*1	Select a value from the left.
Overdischarge detection delay time	toL	38 ms	75 ms	150 ms*1	300 ms	Select a value from the left.
Discharge overcurrent detection delay time	tDIOV	-	4.5 ms	9 ms*1	18 ms	Select a value from the left.
Load short-circuiting detection delay time	t SHORT	-	-	300 μs*1	560 μs	Select a value from the left.
Charge overcurrent detection delay time	tciov	-	4.5 ms	9 ms*1	18 ms	Select a value from the left.

*1. The value is the delay time of the standard products.

Pin Configurations

1. SOT-23-5



2. SNT-6A





Figure 3

	Table 7									
Pin No.	Symbol	Description								
1	NC ^{*1}	No connection								
2	СО	Connection pin of charge control FET gate (CMOS output)								
3	DO	Connection pin of discharge control FET gate (CMOS output)								
4	VSS	Input pin for negative power supply								
5	VDD	Input pin for positive power supply								
6	VM	Voltage detection pin between VM pin and VSS pin (Overcurrent / charger detection pin)								

***1.** The NC pin is electrically open.

The NC pin can be connected to VDD pin or VSS pin.

SII Semiconductor Corporation

Absolute Maximum Ratings

Table 8

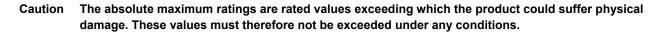
				(Ta = +25°C unless otherwis	se specified)
Iten	n	Symbol	Applied pin	Absolute Maximum Rating	Unit
Input voltage betwe VSS pin	en VDD pin and	V _{DS}	VDD	$V_{\text{SS}} - 0.3$ to $V_{\text{SS}} + 12$	V
VM pin input voltage	/M pin input voltage		VM	$V_{\text{DD}}-28$ to $V_{\text{DD}}+0.3$	V
DO pin output voltage		V _{DO}	DO	$V_{\text{SS}} - 0.3$ to $V_{\text{DD}} + 0.3$	V
CO pin output voltage	ge	Vco	СО	$V_{VM} - 0.3$ to $V_{DD} + 0.3$	V
	SOT-23-5		_	250 (When not mounted on board)	mW
Power dissipation	301-23-5	PD	-	600*1	mW
	SNT-6A		_	400*1	mW
Operation ambient t	Operation ambient temperature		-	-40 to +85	°C
Storage temperatur	e	T _{stg}	_	55 to +125	

*1. When mounted on board

[Mounted board]

(1) Board size: 114.3 mm \times 76.2 mm \times t1.6 mm

(2) Board name: JEDEC STANDARD51-7



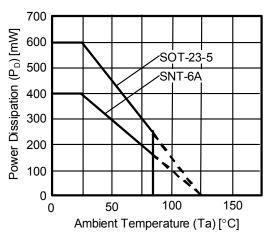


Figure 4 Power Dissipation of Package (When Mounted on Board)

Electrical Characteristics

1. Except detection delay time (Ta = +25°C)

			Die 3		(Ta =	<u>+25°C ur</u>	<u>nless</u> c	otherwise s	pecified)
ltem	Symbol	Condi	tion	Min.	Тур.	Max.	Unit	Test Condition	Test Circuit
Detection Voltage									
Overebarge detection voltage	V _{CU}	3.90 V to 4.50 V, ac	ljustable	V _{CU} - 0.025	V _{CU}	V _{CU} + 0.025	V	1	1
Overcharge detection voltage	VCU	3.90 V to 4.50 V, adjustable, Ta = -5° C to $+55^{\circ}$ C ^{*1}		V _{CU} - 0.03	V _{CU}	V _{CU} + 0.03	V	1	1
Overcharge release voltage	V _{CL}	3.80 V to 4.43 V,	V _{CL} ≠ V _{CU}	V _{CL} - 0.05	V _{CL}	V _{CL} + 0.05	V	1	1
	VOL	adjustable	$V_{CL} = V_{CU}$	V _{CL} - 0.025	V _{CL}	V _{CL} + 0.025	V	1	1
Overdischarge detection voltage	V _{DL}	2.00 V to 3.00 V, ac	ljustable	V _{DL} - 0.05	V _{DL}	V _{DL} + 0.05	V	2	2
Overdischarge release voltage	V _{DU}	2.00 V to 3.40 V,	$V_{\text{DU}} \neq V_{\text{DL}}$	V _{DU} - 0.10	V _{DU}	V _{DU} + 0.10	V	2	2
overalloondige release voltage	•00	adjustable	$V_{DU} = V_{DL}$	V _{DU} - 0.05	V _{DU}	V _{DU} + 0.05	V	2	2
Discharge overcurrent detection voltage	V _{DIOV}	0.05 V to 0.30 V, adjustable		V _{DIOV} - 0.015	V _{DIOV}	V _{DIOV} + 0.015	V	3	2
Load short-circuiting detection voltage*2	VSHORT	_		0.30	0.50	0.70	V	3	2
Charge overcurrent detection voltage	V _{CIOV}	-		-0.13	-0.1	-0.07	V	4	2
0 V Battery Charge Function									
0 V battery charge starting charger voltage	V _{0CHA}	0 V battery charge function "available"		1.2	-	-	V	11	2
0 V battery charge inhibition battery voltage	Voinh	0 V battery charge "unavailable"	function	-	-	0.5	V	12	2
Internal Resistance								•	
Resistance between VM pin and VDD pin	R _{VMD}	V _{DD} = 1.8 V, V _{VM} =	0 V	100	300	900	kΩ	6	3
Resistance between VM pin and VSS pin	R _{VMS}	V_{DD} = 3.5 V, V_{VM} =	1.0 V	10	20	40	kΩ	6	3
Input Voltage		-							
Operation voltage between VDD pin and VSS pin	V _{DSOP1}	-		1.5	-	8	V	-	-
Operation voltage between VDD pin and VM pin	V _{DSOP2}	-		1.5	-	28	V	-	-
Input Current (With Power-down Fund	ction)								
Current consumption during operation	I _{OPE}	V_{DD} = 3.5 V, V_{VM} =	0 V	1.0	3.0	5.5	μΑ	5	2
Current consumption during power-down	I _{PDN}	V_{DD} = V_{VM} = 1.5 V		-	-	0.2	μΑ	5	2
Input Current (Without Power-down F	unction)								
Current consumption during operation	I _{OPE}	V_{DD} = 3.5 V, V_{VM} =	0 V	1.0	3.0	5.5	μΑ	5	2
Current consumption during overdischarge	IOPED	V_{DD} = V_{VM} = 1.5 V		0.3	2.0	3.5	μΑ	5	2
Output Resistance									
CO pin resistance "H"	RCOH	V_{CO} = 3.0 V, V_{DD} = 3	3.5 V, V _{VM} = 0 V	2.5	5	10	kΩ	7	4
CO pin resistance "L"	R _{COL}	V_{CO} = 0.5 V, V_{DD} = 4	4.5 V, V _{VM} = 0 V	2.5	5	10	kΩ	7	4
DO pin resistance "H"	R _{DOH}	V_{DO} = 3.0 V, V_{DD} = 3		2.5	5	10	kΩ	8	4
DO pin resistance "L"	R _{DOL}	V_{DO} = 0.5 V, V_{DD} = 0	V _{VM} = 1.8 V	2.5	5	10	kΩ	8	4

Table 9

*1. Since products are not screened at high and low temperature, the specification for this temperature range is guaranteed by design, not tested in production.

*2. In any conditions, load short-circuiting detection voltage (V_{SHORT}) is higher than discharge overcurrent detection voltage (V_{DIOV}).

2. Except detection delay time (Ta = -40° C to $+85^{\circ}$ C^{*1})

Table 10

				(Ta = -40	°C to +8	35°C ^{*1} un	less o	therwise s	pecified)
Item	Symbol	Condition		Min.	Тур.	Max.	Unit	Test Condition	Test Circuit
Detection Voltage					n		1		
Overcharge detection voltage	Vcu	3.90 V to 4.50 V, adjustable		V _{CU} - 0.060	V _{CU}	V _{CU} + 0.040	V	1	1
	M	3.80 V to 4.43 V,	$V_{CL} \neq V_{CU}$	V _{CL} - 0.08	V _{CL}	V _{CL} + 0.065	V	1	1
Overcharge release voltage	Vcl	adjustable	V _{CL} = V _{CU}	V _{CL} - 0.06	V _{CL}	V _{CL} + 0.04	V	1	1
Overdischarge detection voltage	VDL	2.00 V to 3.00 V, adjust	able	V _{DL} - 0.11	V _{DL}	V _{DL} + 0.13	V	2	2
Quardiachargo ralagoo yelfago	V _{DU}	2.00 V to 3.40 V,	$V_{\text{DU}} \neq V_{\text{DL}}$	V _{DU} - 0.15	V _{DU}	V _{DU} + 0.19	V	2	2
Overdischarge release voltage	VDU	adjustable	V _{DU} = V _{DL}	V _{DU} - 0.11	V _{DU}	V _{DU} + 0.13	V	2	2
Discharge overcurrent detection voltage	V _{DIOV}	0.05 V to 0.30 V, adjustable		V _{DIOV} - 0.021	V _{DIOV}	V _{DIOV} + 0.024	V	3	2
Load short-circuiting detection voltage*2	VSHORT	-	0.16	0.50	0.84	V	3	2	
Charge overcurrent detection voltage	VCIOV	-		-0.14	- 0.1	-0.06	V	4	2
0 V Battery Charge Function									
0 V battery charge starting charger voltage	V _{0CHA}	0 V battery charge function "available"		1.7	-	-	V	11	2
0 V battery charge inhibition battery voltage	V _{0INH}	0 V battery charge funct "unavailable"	tion	-	-	0.3	V	12	2
Internal Resistance									
Resistance between VM pin and VDD pin	R _{VMD}	V_{DD} = 1.8 V, V_{VM} = 0 V		78	300	1310	kΩ	6	3
Resistance between VM pin and VSS pin	R _{VMS}	V_{DD} = 3.5 V, V_{VM} = 1.0 \	/	7.2	20	44	kΩ	6	3
Input Voltage									
Operation voltage between VDD pin and VSS pin	V _{DSOP1}	-		1.5	-	8	V	-	-
Operation voltage between VDD pin and VM pin	V _{DSOP2}	-		1.5	-	28	V	-	-
Input Current (With Power-down Fun	ction)								
Current consumption during operation	I _{OPE}	V_{DD} = 3.5 V, V_{VM} = 0 V		0.7	3.0	6.0	μA	5	2
Current consumption during power-down	I _{PDN}	V_{DD} = V_{VM} = 1.5 V		-	-	0.3	μΑ	5	2
Input Current (Without Power-down F	unction)								
Current consumption during operation	I _{OPE}	V_{DD} = 3.5 V, V_{VM} = 0 V		0.7	3.0	6.0	μA	5	2
Current consumption during overdischarge	I _{OPED}	V_{DD} = V_{VM} = 1.5 V		0.2	2.0	3.8	μA	5	2
Output Resistance							_		
CO pin resistance "H"	R _{COH}	V_{CO} = 3.0 V, V_{DD} = 3.5 V	/, V _{VM} = 0 V	1.2	5	15	kΩ	7	4
CO pin resistance "L"	R _{COL}	V_{CO} = 0.5 V, V_{DD} = 4.5 V	/, V _{VM} = 0 V	1.2	5	15	kΩ	7	4
DO pin resistance "H"	R _{DOH}	V_{DO} = 3.0 V, V_{DD} = 3.5 V	/, V _{VM} = 0 V	1.2	5	15	kΩ	8	4
DO pin resistance "L"	R _{DOL}	V_{DO} = 0.5 V, V_{DD} = V_{VM} =	= 1.8 V	1.2	5	15	kΩ	8	4

*1. Since products are not screened at high and low temperature, the specification for this temperature range is guaranteed by design, not tested in production.

*2. In any conditions, load short-circuiting detection voltage (V_{SHORT}) is higher than discharge overcurrent detection voltage (V_{DIOV}).

Rev.7.7_02

3. Detection delay time

 S-8211CAA, S-8211CAH, S-8211CAI, S-8211CAJ, S-8211CAK, S-8211CAL, S-8211CAM, S-8211CAN, S-8211CAR, S-8211CAS, S-8211CAU, S-8211CAY, S-8211CAZ, S-8211CBA, S-8211CBB, S-8211CBF, S-8211CBH, S-8211CBW, S-8211CCB, S-8211CCD, S-8211CCG, S-8211CCK, S-8211CCN, S-8211CCQ, S-8211CCR, S-8211CCT, S-8211CCV, S-8211CDA, S-8211CDB, S-8211CDC, S-8211CDG, S-8211CDJ, S-8211CDM, S-8211CDN, S-8211CDO

ltem	Symbol	Condition	Min.	Тур.	Max.	Unit	Test Condition	Test Circuit
Delay Time (Ta = +25°C)								
Overcharge detection delay time	t _{cu}	-	0.96	1.2	1.4	S	9	5
Overdischarge detection delay time	t _{DL}	-	120	150	180	ms	9	5
Discharge overcurrent detection delay time	t _{DIOV}	-	7.2	9	11	ms	10	5
Load short-circuiting detection delay time	t _{SHORT}	-	240	300	360	μs	10	5
Charge overcurrent detection delay time	t _{CIOV}	-	7.2	9	11	ms	10	5
Delay Time (Ta = –40°C to +85°C) ^{*1}								
Overcharge detection delay time	t _{cu}	-	0.7	1.2	2.0	S	9	5
Overdischarge detection delay time	t _{DL}	-	83	150	255	ms	9	5
Discharge overcurrent detection delay time	t _{DIOV}	-	5	9	15	ms	10	5
Load short-circuiting detection delay time	t _{SHORT}	-	150	300	540	μs	10	5
Charge overcurrent detection delay time	t _{CIOV}	-	5	9	15	ms	10	5

Table 11

*1. Since products are not screened at high and low temperature, the specification for this temperature range is guaranteed by design, not tested in production.

Table 12

3. 2 S-8211CAB, S-8211CAV

Item	Symbol	Condition	Min.	Тур.	Max.	Unit	Test Condition	Test Circuit
Delay Time (Ta = +25°C)								
Overcharge detection delay time	t _{CU}	-	0.96	1.2	1.4	S	9	5
Overdischarge detection delay time	t _{DL}	-	120	150	180	ms	9	5
Discharge overcurrent detection delay time	t _{DIOV}	-	7.2	9	11	ms	10	5
Load short-circuiting detection delay time	t _{SHORT}	-	450	560	670	μs	10	5
Charge overcurrent detection delay time	t _{CIOV}	-	7.2	9	11	ms	10	5
Delay Time (Ta = –40°C to +85°C) ^{*1}								
Overcharge detection delay time	tcu	-	0.7	1.2	2.0	S	9	5
Overdischarge detection delay time	t _{DL}	-	83	150	255	ms	9	5
Discharge overcurrent detection delay time	t DIOV	-	5	9	15	ms	10	5
Load short-circuiting detection delay time	t SHORT	-	260	560	940	μs	10	5
Charge overcurrent detection delay time	t _{CIOV}	-	5	9	15	ms	10	5

3.3 S-8211CAD, S-8211CCW

Table 13 Test Test Condition Item Symbol Min. Typ. Max. Unit Condition Circuit Delay Time (Ta = +25°C) 115 143 172 ms 9 5 Overcharge detection delay time t_{CU} _ 30 38 46 9 5 t_{DL} _ ms Overdischarge detection delay time t_{DIOV} 18 22 10 Discharge overcurrent detection delay time 14.5 ms 5 _ 240 300 360 10 5 Load short-circuiting detection delay time **t**SHORT _ μs 7.2 9 10 5 Charge overcurrent detection delay time tciov _ 11 ms Delay Time (Ta = –40°C to +85°C)^{*1} tcu 82 143 240 ms 9 5 Overcharge detection delay time _ 20 38 65 9 5 Overdischarge detection delay time ms t_{DL} _ 10 5 30 Discharge overcurrent detection delay time t_{DIOV} _ 10 18 ms Load short-circuiting detection delay time **t**SHORT 150 300 540 μs 10 5 _ 5 9 15 ms 10 5 Charge overcurrent detection delay time tciov

*1. Since products are not screened at high and low temperature, the specification for this temperature range is guaranteed by design, not tested in production.

3.4 S-8211CAE, S-8211CAT, S-8211CAX, S-8211CBR, S-8211CBV, S-8211CBZ, S-8211CCM, S-8211CCY, S-8211CCZ

ltem	Symbol	Condition	Min.	Тур.	Max.	Unit	Test Condition	Test Circuit
Delay Time (Ta = +25°C)								
Overcharge detection delay time	tcu	-	0.96	1.2	1.4	S	9	5
Overdischarge detection delay time	t _{DL}	-	120	150	180	ms	9	5
Discharge overcurrent detection delay time	t _{DIOV}	-	14.5	18	22	ms	10	5
Load short-circuiting detection delay time	t _{SHORT}	-	240	300	360	μs	10	5
Charge overcurrent detection delay time	t _{CIOV}	-	7.2	9	11	ms	10	5
Delay Time (Ta = –40°C to +85°C) ^{*1}								
Overcharge detection delay time	t _{cu}	-	0.7	1.2	2.0	S	9	5
Overdischarge detection delay time	t _{DL}	-	83	150	255	ms	9	5
Discharge overcurrent detection delay time	t _{DIOV}	-	10	18	30	ms	10	5
Load short-circuiting detection delay time	t _{SHORT}	-	150	300	540	μs	10	5
Charge overcurrent detection delay time	t _{CIOV}	-	5	9	15	ms	10	5

Table 14

3. 5 S-8211CAF, S-8211CAO, S-8211CAP, S-8211CAQ, S-8211CBD, S-8211CBJ, S-8211CBO, S-8211CCC, S-8211CCF, S-8211CCI, S-8211CCJ, S-8211CCU, S-8211CCZ, S-8211CDE, S-8211CDF, S-8211CDH, S-8211CDL, S-8211CDL

Item	Symbol	Condition	Min.	Тур.	Max.	Unit	Test Condition	Test Circuit
Delay Time (Ta = +25°C)								
Overcharge detection delay time	t _{CU}	_	0.96	1.2	1.4	S	9	5
Overdischarge detection delay time	t _{DL}	-	30	38	46	ms	9	5
Discharge overcurrent detection delay time	t _{DIOV}	-	7.2	9	11	ms	10	5
Load short-circuiting detection delay time	t _{SHORT}	-	240	300	360	μs	10	5
Charge overcurrent detection delay time	t _{CIOV}	-	7.2	9	11	ms	10	5
Delay Time (Ta = –40°C to +85°C) ^{*1}								
Overcharge detection delay time	t _{CU}	-	0.7	1.2	2.0	S	9	5
Overdischarge detection delay time	t _{DL}	-	20	38	65	ms	9	5
Discharge overcurrent detection delay time	t _{DIOV}	-	5	9	15	ms	10	5
Load short-circuiting detection delay time	t _{SHORT}	-	150	300	540	μs	10	5
Charge overcurrent detection delay time	t _{CIOV}	-	5	9	15	ms	10	5

Table 15

*1. Since products are not screened at high and low temperature, the specification for this temperature range is guaranteed by design, not tested in production.

3.6 S-8211CAW, S-8211CDD

Item	Symbol	Condition	Min.	Тур.	Max.	Unit	Test Condition	Test Circuit
Delay Time (Ta = +25°C)								
Overcharge detection delay time	t _{cu}	_	0.96	1.2	1.4	S	9	5
Overdischarge detection delay time	t _{DL}	_	120	150	180	ms	9	5
Discharge overcurrent detection delay time	t _{DIOV}	_	3.6	4.5	5.4	ms	10	5
Load short-circuiting detection delay time	t SHORT	_	240	300	360	μs	10	5
Charge overcurrent detection delay time	t _{CIOV}	-	7.2	9	11	ms	10	5
Delay Time (Ta = –40°C to +85°C) ^{*1}								
Overcharge detection delay time	tcu	_	0.7	1.2	2.0	s	9	5
Overdischarge detection delay time	t _{DL}	-	83	150	255	ms	9	5
Discharge overcurrent detection delay time	t _{DIOV}	_	2.5	4.5	7.7	ms	10	5
Load short-circuiting detection delay time	t _{SHORT}	_	150	300	540	μs	10	5
Charge overcurrent detection delay time	t _{CIOV}	-	5	9	15	ms	10	5

Table 16

3.7 S-8211CBN

Table 17									
ltem	Symbol	Condition	Min.	Тур.	Max.	Unit	Test Condition	Test Circuit	
Delay Time (Ta = +25°C)									
Overcharge detection delay time	t _{CU}	-	458	573	687	ms	9	5	
Overdischarge detection delay time	t _{DL}	-	120	150	180	ms	9	5	
Discharge overcurrent detection delay time	t _{DIOV}	-	3.6	4.5	5.4	ms	10	5	
Load short-circuiting detection delay time	t _{SHORT}	-	240	300	360	μs	10	5	
Charge overcurrent detection delay time	t _{CIOV}	-	3.6	4.5	5.4	ms	10	5	
Delay Time (Ta = –40°C to +85°C) ^{*1}									
Overcharge detection delay time	t _{CU}	-	334	573	955	ms	9	5	
Overdischarge detection delay time	t _{DL}	-	83	150	255	ms	9	5	
Discharge overcurrent detection delay time	t _{DIOV}	-	2.5	4.5	7.7	ms	10	5	
Load short-circuiting detection delay time	t _{SHORT}	-	150	300	540	μs	10	5	
Charge overcurrent detection delay time	t _{CIOV}	-	2.5	4.5	7.7	ms	10	5	

*1. Since products are not screened at high and low temperature, the specification for this temperature range is guaranteed by design, not tested in production.

3.8 S-8211CCE, S-8211CCH, S-8211CCJ

Table 18

Item	Symbol	Condition	Min.	Тур.	Max.	Unit	Test Condition	Test Circuit
Delay Time (Ta = +25°C)								
Overcharge detection delay time	tcu	-	0.96	1.2	1.4	S	9	5
Overdischarge detection delay time	t _{DL}	-	61	75	90	ms	9	5
Discharge overcurrent detection delay time	t _{DIOV}	-	7.2	9	11	ms	10	5
Load short-circuiting detection delay time	t _{SHORT}	-	240	300	360	μs	10	5
Charge overcurrent detection delay time	t _{CIOV}	-	7.2	9	11	ms	10	5
Delay Time (Ta = –40°C to +85°C) ^{*1}							-	-
Overcharge detection delay time	t _{cu}	-	0.7	1.2	2.0	S	9	5
Overdischarge detection delay time	t _{DL}	-	41	75	128	ms	9	5
Discharge overcurrent detection delay time	t _{DIOV}	-	5	9	15	ms	10	5
Load short-circuiting detection delay time	t _{SHORT}	-	150	300	540	μs	10	5
Charge overcurrent detection delay time	t _{CIOV}	-	5	9	15	ms	10	5

3.9 S-8211CDP

Table 19									
ltem	Symbol	Condition	Min.	Тур.	Max.	Unit	Test Condition	Test Circuit	
Delay Time (Ta = +25°C)									
Overcharge detection delay time	tcu	-	0.96	1.2	1.4	S	9	5	
Overdischarge detection delay time	t _{DL}	-	240	300	360	ms	9	5	
Discharge overcurrent detection delay time	t _{DIOV}	-	7.2	9	11	ms	10	5	
Load short-circuiting detection delay time	t _{SHORT}	-	240	300	360	μs	10	5	
Charge overcurrent detection delay time	t _{CIOV}	-	7.2	9	11	ms	10	5	
Delay Time (Ta = –40°C to +85°C) ^{*1}									
Overcharge detection delay time	tcu	-	0.7	1.2	2.0	s	9	5	
Overdischarge detection delay time	t _{DL}	-	166	300	510	ms	9	5	
Discharge overcurrent detection delay time	t _{DIOV}	-	5	9	15	ms	10	5	
Load short-circuiting detection delay time	t _{SHORT}	-	150	300	540	μs	10	5	
Charge overcurrent detection delay time	t _{CIOV}	-	5	9	15	ms	10	5	

Test Circuits

Caution Unless otherwise specified, the output voltage levels "H" and "L" at CO pin (V_{CO}) and DO pin (V_{DO}) are judged by the threshold voltage (1.0 V) of the N-channel FET. Judge the CO pin level with respect to V_{VM} and the DO pin level with respect to V_{SS}.

1. Overcharge detection voltage, overcharge release voltage (Test condition 1, test circuit 1)

Overcharge detection voltage (V_{CU}) is defined as the voltage between the VDD pin and VSS pin at which V_{CO} goes from "H" to "L" when the voltage V1 is gradually increased from the starting condition of V1 = 3.5 V. Overcharge release voltage (V_{CL}) is defined as the voltage between the VDD pin and VSS pin at which V_{CO} goes from "L" to "H" when the voltage V1 is then gradually decreased. Overcharge hysteresis voltage (V_{HC}) is defined as the difference between overcharge detection voltage (V_{CU}) and overcharge release voltage (V_{CL}).

2. Overdischarge detection voltage, overdischarge release voltage (Test condition 2, test circuit 2)

Overdischarge detection voltage (V_{DL}) is defined as the voltage between the VDD pin and VSS pin at which V_{DO} goes from "H" to "L" when the voltage V1 is gradually decreased from the starting condition of V1 = 3.5 V, V2 = 0 V. Overdischarge release voltage (V_{DU}) is defined as the voltage between the VDD pin and VSS pin at which V_{DO} goes from "L" to "H" when the voltage V1 is then gradually increased. Overdischarge hysteresis voltage (V_{HD}) is defined as the difference between overdischarge release voltage (V_{DU}) and overdischarge detection voltage (V_{DL}).

3. Discharge overcurrent detection voltage (Test condition 3, test circuit 2)

Discharge overcurrent detection voltage (V_{DIOV}) is defined as the voltage between the VM pin and VSS pin whose delay time for changing V_{DO} from "H" to "L" lies between the minimum and the maximum value of discharge overcurrent delay time when the voltage V2 is increased rapidly (within 10 μ s) from the starting condition of V1 = 3.5 V, V2 = 0 V.

4. Load short-circuiting detection voltage (Test condition 3, test circuit 2)

Load short-circuiting detection voltage (V_{SHORT}) is defined as the voltage between the VM pin and VSS pin whose delay time for changing V_{DO} from "H" to "L" lies between the minimum and the maximum value of load short-circuiting delay time when the voltage V2 is increased rapidly (within 10 μ s) from the starting condition of V1 = 3.5 V, V2 = 0 V.

5. Charge overcurrent detection voltage (Test condition 4, test circuit 2)

Charge overcurrent detection voltage (V_{CIOV}) is defined as the voltage between the VM pin and VSS pin whose delay time for changing V_{CO} from "H" to "L" lies between the minimum and the maximum value of charge overcurrent delay time when the voltage V2 is decreased rapidly (within 10 µs) from the starting condition of V1 = 3.5 V, V2 = 0 V.

6. Current consumption during operation (Test condition 5, test circuit 2)

The current consumption during operation (I_{OPE}) is the current that flows through the VDD pin (I_{DD}) under the set conditions of V1 = 3.5 V and V2 = 0 V (normal status).

7. Current consumption during power-down, current consumption during overdischarge (Test condition 5, test circuit 2)

7.1 With power-down function

The current consumption during power-down (I_{PDN}) is the current that flows through the VDD pin (I_{DD}) under the set condition of V1 = V2 = 1.5 V (overdischarge status).

7.2 Without power-down function

The current consumption during overdischarge (I_{OPED}) is the current that flows through the VDD pin (I_{DD}) under the set condition of V1 = V2 = 1.5 V (overdischarge status).

8. Resistance between VM pin and VDD pin (Test condition 6, test circuit 3)

The resistance between VM pin and VDD pin (R_{VMD}) is the resistance between VM pin and VDD pin under the set conditions of V1 = 1.8 V, V2 = 0 V.

9. Resistance between VM pin and VSS pin (Test condition 6, test circuit 3)

The resistance between VM pin and VSS pin (R_{VMS}) is the resistance between VM pin and VSS pin under the set conditions of V1 = 3.5 V, V2 = 1.0 V.

10. CO pin resistance "H" (Test condition 7, test circuit 4)

The CO pin resistance "H" (R_{COH}) is the resistance at the CO pin under the set conditions of V1 = 3.5 V, V2 = 0 V, V3 = 3.0 V.

11. CO pin resistance "L" (Test condition 7, test circuit 4)

The CO pin resistance "L" (R_{COL}) is the resistance at the CO pin under the set conditions of V1 = 4.5 V, V2 = 0 V, V3 = 0.5 V.

12. DO pin resistance "H" (Test condition 8, test circuit 4)

The DO pin resistance "H" (R_{DOH}) is the resistance at the DO pin under the set conditions of V1 = 3.5 V, V2 = 0 V, V4 = 3.0 V.

13. DO pin resistance "L" (Test condition 8, test circuit 4)

The DO pin resistance "L" (R_{DOL}) is the resistance at the DO pin under the set conditions of V1 = 1.8 V, V2 = 0 V, V4 = 0.5 V.

14. Overcharge detection delay time (Test condition 9, test circuit 5)

The overcharge detection delay time (t_{CU}) is the time needed for V_{CO} to change from "H" to "L" just after the voltage V1 momentarily increases (within 10 μ s) from overcharge detection voltage (V_{CU}) – 0.2 V to overcharge detection voltage (V_{CU}) + 0.2 V under the set condition of V2 = 0 V.

15. Overdischarge detection delay time (Test condition 9, test circuit 5)

The overdischarge detection delay time (t_{DL}) is the time needed for V_{DO} to change from "H" to "L" just after the voltage V1 momentarily decreases (within 10 μ s) from overdischarge detection voltage (V_{DL}) + 0.2 V to overdischarge detection voltage (V_{DL}) – 0.2 V under the set condition of V2 = 0 V.

16. Discharge overcurrent detection delay time (Test condition 10, test circuit 5)

Discharge overcurrent detection delay time (t_{DIOV}) is the time needed for V_{DO} to go to "L" after the voltage V2 momentarily increases (within 10 µs) from 0 V to 0.35 V under the set conditions of V1 = 3.5 V, V2 = 0 V.

17. Load short-circuiting detection delay time (Test condition 10, test circuit 5)

Load short-circuiting detection delay time (t_{SHORT}) is the time needed for V_{DO} to go to "L" after the voltage V2 momentarily increases (within 10 μ s) from 0 V to 1.6 V under the set conditions of V1 = 3.5 V, V2 = 0 V.

18. Charge overcurrent detection delay time (Test condition 10, test circuit 5)

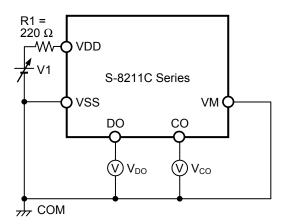
Charge overcurrent detection delay time (t_{CIOV}) is the time needed for V_{CO} to go to "L" after the voltage V2 momentarily decreases (within 10 µs) from 0 V to – 0.3 V under the set conditions of V1 = 3.5 V, V2 = 0 V.

19. 0 V battery charge starting charger voltage (0 V battery charge function "available") (Test condition 11, test circuit 2)

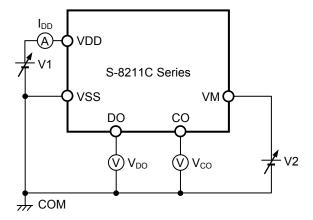
The 0 V battery charge starting charger voltage (V_{0CHA}) is defined as the voltage between the VDD pin and VM pin at which V_{CO} goes to "H" (V_{VM} + 0.1 V or higher) when the voltage V2 is gradually decreased from the starting condition of V1 = V2 = 0 V.

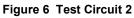
20. 0 V battery charge inhibition battery voltage (0 V battery charge function "unavailable") (Test condition 12, test circuit 2)

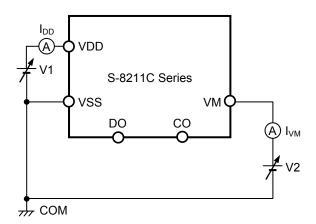
The 0 V battery charge inhibition battery voltage (V_{0INH}) is defined as the voltage between the VDD pin and VSS pin at which V_{CO} goes to "H" (V_{VM} + 0.1 V or higher) when the voltage V1 is gradually increased from the starting conditions of V1 = 0 V, V2 = -4 V.



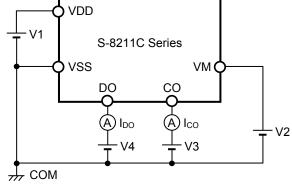




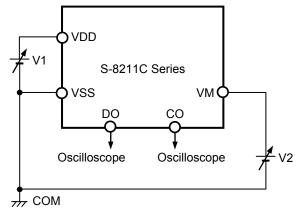














Operation

Remark Refer to "
Battery Protection IC Connection Example".

1. Normal status

The S-8211C Series monitors the voltage of the battery connected between the VDD pin and VSS pin and the voltage difference between the VM pin and VSS pin to control charging and discharging. When the battery voltage is in the range from overdischarge detection voltage (V_{DL}) to overcharge detection voltage (V_{CU}), and the VM pin voltage is in the range from the charge overcurrent detection voltage (V_{CIOV}) to discharge overcurrent detection voltage (V_{DIOV}), the S-8211C Series turns both the charging and discharging control FETs on. This condition is called the normal status, and in this condition charging and discharging can be carried out freely.

The resistance (R_{VMD}) between the VM pin and VDD pin, and the resistance (R_{VMS}) between the VM pin and VSS pin are not connected in the normal status.

Caution When the battery is connected for the first time, discharging may not be enabled. In this case, short the VM pin and VSS pin, or set the VM pin's voltage at the level of the charge overcurrent detection voltage (V_{CIOV}) or more and the discharge overcurrent detection voltage (V_{DIOV}) or less by connecting the charger. The S-8211C Series then returns to the normal status.

2. Overcharge status

When the battery voltage becomes higher than overcharge detection voltage (V_{CU}) during charging in the normal status and detection continues for the overcharge detection delay time (t_{CU}) or longer, the S-8211C Series turns the charging control FET off to stop charging. This condition is called the overcharge status.

The resistance (R_{VMD}) between the VM pin and VDD pin, and the resistance (R_{VMS}) between the VM pin and VSS pin are not connected in the overcharge status.

The overcharge status is released in the following two cases ((1) and (2)).

- (1) In the case that the VM pin voltage is higher than or equal to the charge overcurrent detection voltage (V_{CIOV}), and is lower than the discharge overcurrent detection voltage (V_{DIOV}), the S-8211C Series releases the overcharge status when the battery voltage falls below the overcharge release voltage (V_{CL}).
- (2) In the case that the VM pin voltage is higher than or equal to the discharge overcurrent detection voltage (V_{DIOV}), the S-8211C Series releases the overcharge status when the battery voltage falls below the overcharge detection voltage (V_{CU}).

The discharge is started by connecting a load after the overcharge detection, the VM pin voltage rises more than the VSS pin voltage due to the V_f voltage of the parasitic diode, because the discharge current flows through the parasitic diode in the charging control FET. If this VM pin voltage is higher than or equal to the discharge overcurrent detection voltage (V_{DIOV}), the S-8211C Series releases the overcharge status when the battery voltage is lower than or equal to the overcharge detection voltage (V_{CU}).

For the actual application boards, changing the battery voltage and the charger voltage simultaneously enables to measure the overcharge release voltage (V_{CL}). In this case, the charger is always necessary to have the equivalent voltage level to the battery voltage. The charger keeps VM pin voltage higher than or equal to the charge overcurrent detection voltage (V_{CIOV}) and lower than or equal to the discharge overcurrent detection voltage (V_{CIOV}) and lower than or equal to the battery voltage falls below the overcharge release voltage (V_{CIOV}).

- Caution 1. If the battery is charged to a voltage higher than overcharge detection voltage (V_{cu}) and the battery voltage does not fall below overcharge detection voltage (V_{cu}) even when a heavy load is connected, discharge overcurrent detection and load short-circuiting detection do not function until the battery voltage falls below overcharge detection voltage (V_{cu}). Since an actual battery has an internal impedance of tens of mΩ, the battery voltage drops immediately after a heavy load that causes overcurrent is connected, and discharge overcurrent detection and load short-circuiting detection and load short-circuiting detection and load short-circuiting detection and load short-circuiting detection function.
 - 2. When a charger is connected after overcharge detection, the overcharge status is not released even if the battery voltage is below overcharge release voltage (V_{CL}). The overcharge status is released when the VM pin voltage goes over the charge overcurrent detection voltage (V_{CIOV}) by removing the charger.

3. Overdischarge status

3.1 With power-down function

When the battery voltage falls below overdischarge detection voltage (V_{DL}) during discharging in the normal status and the detection continues for the overdischarge detection delay time (t_{DL}) or longer, the S-8211C Series turns the discharging control FET off to stop discharging. This condition is called the overdischarge status. Under the overdischarge status, the VM pin voltage is pulled up by the resistor between the VM pin and VDD pin in the S-8211C Series (R_{VMD}). When voltage difference between the VM pin and VDD pin then is 1.3 V typ. or lower, the current consumption is reduced to the power-down current consumption (I_{PDN}). This condition is called the power-down status.

The resistance (R_{VMS}) between the VM pin and VSS pin is not connected in the power-down status and the overdischarge status.

The power-down status is released when a charger is connected and the voltage difference between the VM pin and VDD pin becomes 1.3 V typ. or higher.

When a battery in the overdischarge status is connected to a charger and provided that the VM pin voltage is lower than -0.7 V typ., the S-8211C Series releases the overdischarge status and turns the discharging FET on when the battery voltage reaches overdischarge detection voltage (V_{DL}) or higher.

When a battery in the overdischarge status is connected to a charger and provided that the VM pin voltage is not lower than -0.7 V typ., the S-8211C Series releases the overdischarge status when the battery voltage reaches overdischarge release voltage (V_{DU}) or higher.

3. 2 Without power-down function

When the battery voltage falls below overdischarge detection voltage (V_{DL}) during discharging in the normal status and the detection continues for the overdischarge detection delay time (t_{DL}) or longer, the S-8211C Series turns the discharging control FET off to stop discharging. This condition is called the overdischarge status. Under the overdischarge status, the VM pin voltage is pulled up by the resistor between the VM pin and VDD pin in the S-8211C Series (R_{VMD}).

The resistance (R_{VMS}) between the VM pin and VSS pin is not connected in the overdischarge status.

When a battery in the overdischarge status is connected to a charger and provided that the VM pin voltage is lower than -0.7 V typ., the S-8211C Series releases the overdischarge status and turns the discharging FET on when the battery voltage reaches overdischarge detection voltage (V_{DL}) or higher.

When a battery in the overdischarge status is connected to a charger and provided that the VM pin voltage is not lower than -0.7 V typ., the S-8211C Series releases the overdischarge status when the battery voltage reaches overdischarge release voltage (V_{DU}) or higher.

4. Discharge overcurrent status (discharge overcurrent, load short-circuiting)

When a battery in the normal status is in the status where the VM pin voltage is equal to or higher than the discharge overcurrent detection voltage (V_{DIOV}) because the discharge current is higher than the specified value and the status lasts for the discharge overcurrent detection delay time (t_{DIOV}), the discharge control FET is turned off and discharging is stopped. This status is called the discharge overcurrent status.

In the discharge overcurrent status, the VM pin and VSS pin are shorted by the resistor between VM pin and VSS pin (R_{VMS}) in the S-8211C Series. However, the VM pin voltage is at the V_{DD} potential due to the load as long as the load is connected. When the load is disconnected completely, the VM pin returns to the V_{SS} potential.

If the S-8211C Series detects that the VM pin voltage returns to discharge overcurrent detection voltage (V_{DIOV}) or lower, the discharge overcurrent status is restored to the normal status.

The S-8211C Series will be restored to the normal status from discharge overcurrent detection status even when the VM pin voltage becomes the discharge overcurrent detection voltage (V_{DIOV}) or lower by connecting the charger.

The resistance (R_{VMD}) between the VM pin and VDD pin is not connected in the discharge overcurrent status.

5. Charge overcurrent status

When a battery in the normal status is in the status where the VM pin voltage is lower than the charge overcurrent detection voltage (V_{CIOV}) because the charge current is higher than the specified value and the status lasts for the charge overcurrent detection delay time (t_{CIOV}), the charge control FET is turned off and charging is stopped. This status is called the charge overcurrent status.

The S-8211C Series will be restored to the normal status from the charge overcurrent status when the VM pin voltage returns to charge overcurrent detection voltage (V_{CIOV}) or higher by removing the charger.

The charge overcurrent detection function does not work in the overdischarge status.

The resistance (R_{VMD}) between the VM pin and VDD pin, and the resistance (R_{VMS}) between the VM pin and VSS pin are not connected in the charge overcurrent status.

6. 0 V Battery charge function "available"

This function is used to recharge a connected battery whose voltage is 0 V due to self-discharge. When the 0 V battery charge starting charger voltage (V_{0CHA}) or a higher voltage is applied between the EB+ and EB- pins by connecting a charger, the charging control FET gate is fixed to the VDD pin voltage.

When the voltage between the gate and source of the charging control FET becomes equal to or higher than the turnon voltage due to the charger voltage, the charging control FET is turned on to start charging. At this time, the discharging control FET is off and the charging current flows through the internal parasitic diode in the discharging control FET. When the battery voltage becomes equal to or higher than overdischarge release voltage (V_{DU}), the S-8211C Series enters the normal status.

- Caution 1. Some battery providers do not recommend charging for a completely self-discharged battery. Please ask the battery provider to determine whether to enable or inhibit the 0 V battery charge function.
 - 2. The 0 V battery charge function has higher priority than the charge overcurrent detection function. Consequently, a product in which use of the 0 V battery charge function is enabled charges a battery forcibly and the charge overcurrent cannot be detected when the battery voltage is lower than overdischarge detection voltage (V_{DL}).

7. 0 V Battery charge function "unavailable"

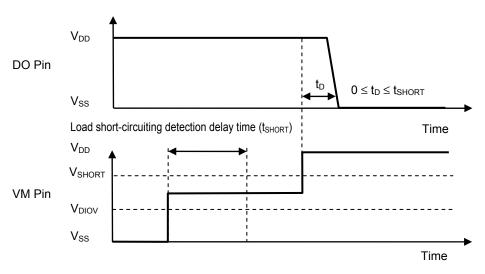
This function inhibits recharging when a battery that is internally short-circuited (0 V battery) is connected. When the battery voltage is the 0 V battery charge inhibition battery voltage (V_{0INH}) or lower, the charging control FET gate is fixed to the EB– pin voltage to inhibit charging. When the battery voltage is the 0 V battery charge inhibition battery voltage (V_{0INH}) or lower, the charging control FET gate is voltage (V_{0INH}) or higher, charging can be performed.

Caution Some battery providers do not recommend charging for a completely self-discharged battery. Please ask the battery provider to determine whether to enable or inhibit the 0 V battery charge function.

8. Delay circuit

The detection delay times are determined by dividing a clock of approximately 3.5 kHz by the counter.

Remark 1. The discharge overcurrent detection delay time (t_{DIOV}) and the load short-circuiting detection delay time (t_{SHORT}) start when the discharge overcurrent detection voltage (V_{DIOV}) is detected. When the load short-circuiting detection voltage (V_{SHORT}) is detected over the load short-circuiting detection delay time (t_{SHORT}) after the detection of discharge overcurrent detection voltage (V_{DIOV}), the S-8211C Series turns the discharging control FET off within the load short-circuiting detection delay time (t_{SHORT}) from the time of detecting V_{SHORT}.





2. With power-down function

When any overcurrent is detected and the overcurrent continues for longer than the overdischarge detection delay time (t_{DL}) without the load being released, the status changes to the power-down status at the point where the battery voltage falls below overdischarge detection voltage (V_{DL}).

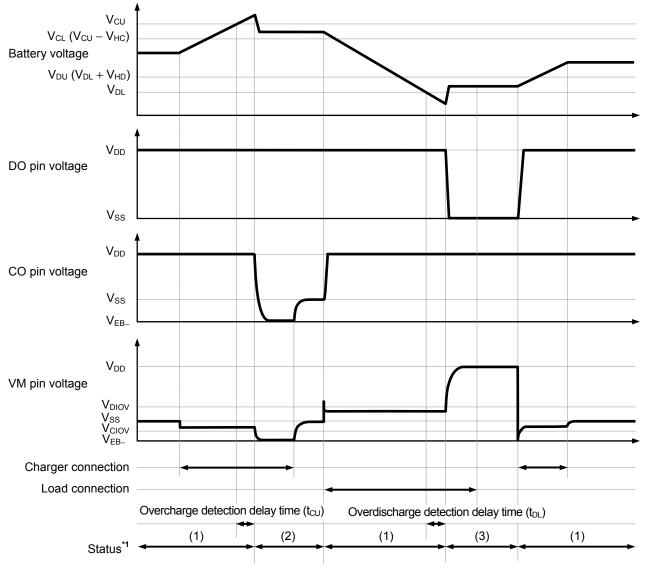
When the battery voltage falls below overdischarge detection voltage (V_{DL}) due to overcurrent, the S-8211C Series turns the discharging control FET off via overcurrent detection. In this case, if the recovery of the battery voltage is so slow that the battery voltage after the overdischarge detection delay time (t_{DL}) is still lower than the overdischarge detection voltage (V_{DL}), the S-8211C Series shifts to the power-down status.

Without power-down function

When any overcurrent is detected and the overcurrent continues for longer than the overdischarge detection delay time (t_{DL}) without the load being released, the status changes to the overdischarge status at the point where the battery voltage falls below overdischarge detection voltage (V_{DL}).

When the battery voltage falls below overdischarge detection voltage (V_{DL}) due to overcurrent, the S-8211C Series turns the discharging control FET off via overcurrent detection. In this case, if the recovery of the battery voltage is so slow that the battery voltage after the overdischarge detection delay time (t_{DL}) is still lower than the overdischarge detection voltage (V_{DL}), the S-8211C Series shifts to the overdischarge status.

Timing Charts



1. Overcharge detection, overdischarge detection

*1. (1): Normal status

(2): Overcharge status

(3): Overdischarge status

Remark The charger is assumed to charge with a constant current.

Figure 11

V_{CU} V_{CL} (V_{CU} - V_{HC}) Battery voltage $V_{DU} (V_{DL} + V_{HD}) V_{DL}$ V_{DD} DO pin voltage V_{SS} V_{DD} CO pin voltage V_{SS} V_{DD} VM pin voltage VSHORT V_{DIOV} Vss Load connection Load short-circuiting detection delay time (t_{SHORT}) Discharge overcurrent detection delay time (t_{DIOV}) (1) (2) (1) (2) (1)

2. Discharge overcurrent detection

*1. (1): Normal status

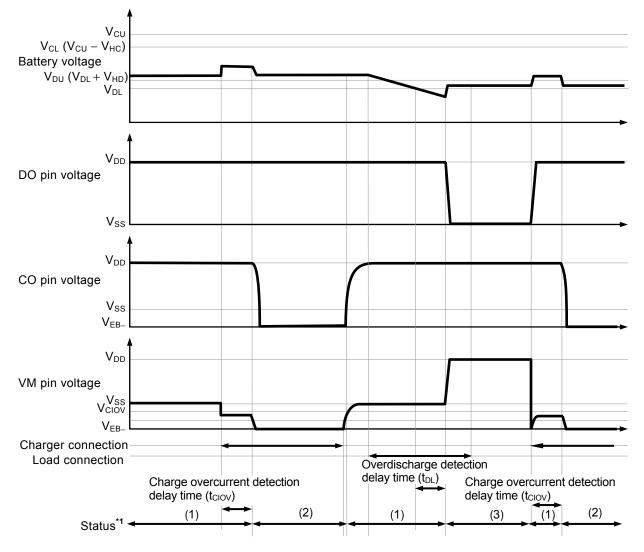
(2): Discharge overcurrent status

Status^{*1}

Remark The charger is assumed to charge with a constant current.

Figure 12

Rev.7.7_02



3. Charge overcurrent detection

*1. (1): Normal status

(2): Charge overcurrent status

(3): Overdischarge status

Remark The charger is assumed to charge with a constant current.

Figure 13

Battery Protection IC Connection Example

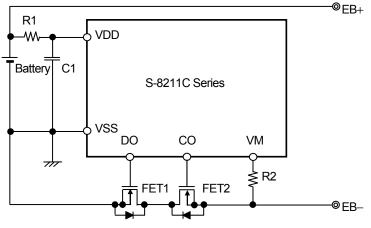


Figure 14

Symbol	Part	Purpose	Min.	Тур.	Max.	Remark
FET1	N-channel MOS FET	Discharge control	_	_	_	Threshold voltage \leq Overdischarge detection voltage ^{*1} Gate to source withstand voltage \geq Charger voltage ^{*2}
FET2	N-channel MOS FET	Charge control	_	_	_	Threshold voltage \leq Overdischarge detection voltage ^{*1} Gate to source withstand voltage \geq Charger voltage ^{*2}
R1	Resistor	ESD protection, For power fluctuation	100 Ω	220 Ω	330 Ω	Resistance should be as small as possible to avoid lowering the overcharge detection accuracy due to current consumption. ^{*3}
C1	Capacitor	For power fluctuation	0.022 μF	0.1 μF	1.0 μF	Connect a capacitor of 0.022 μF or higher between VDD pin and VSS pin.*4
R2	Resistor	Protection for reverse connection of a charger	300 Ω	2 kΩ	2 kΩ	Select as large a resistance as possible to prevent current when a charger is connected in reverse. ^{*5}

*1. If the threshold voltage of an FET is low, the FET may not cut the charge current. If an FET with a threshold voltage equal to or higher than the overdischarge detection voltage is used, discharging may be stopped before overdischarge is detected.

*2. If the withstand voltage between the gate and source is lower than the charger voltage, the FET may be destroyed.

*3. If a high resistor is connected to R1, the voltage between VDD pin and VSS pin may exceed the absolute maximum rating when a charger is connected in reverse since the current flows from the charger to the IC. Insert a resistor of 100 Ω or higher as R1 for ESD protection.

*4. If a capacitor of less than 0.022 μF is connected to C1, DO pin may oscillate when load short-circuiting is detected. Be sure to connect a capacitor of 0.022 μF or higher to C1.

*5. If a resistor of 2 k Ω or higher is connected to R2, the charge current may not be cut when a high-voltage charger is connected.

Caution 1. The above constants may be changed without notice.

2. It has not been confirmed whether the operation is normal or not in circuits other than the above example of connection. In addition, the example of connection shown above and the constant do not guarantee proper operation. Perform thorough evaluation using the actual application to set the constant.

Precautions

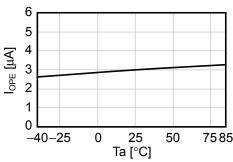
- The application conditions for the input voltage, output voltage, and load current should not exceed the package power dissipation.
- Do not apply an electrostatic discharge to this IC that exceeds the performance ratings of the built-in electrostatic protection circuit.
- SII Semiconductor Corporation claims no responsibility for any and all disputes arising out of or in connection with any infringement by products including this IC of patents owned by a third party.

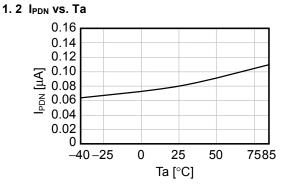
Rev.7.7_02

Characteristics (Typical Data)

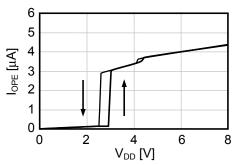
1. Current consumption



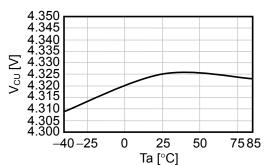




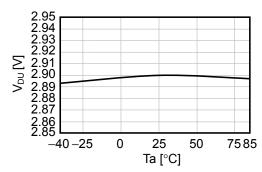
1. 3 IOPE VS. VDD



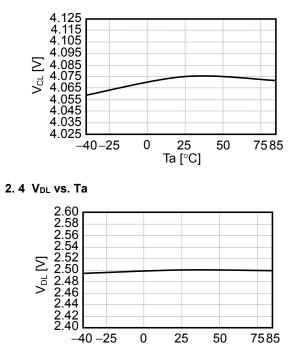
- 2. Overcharge detection / release voltage, overdischarge detection / release voltage, overcurrent detection voltage, and delay time
 - 2. 1 Vcu vs. Ta



2. 3 VDU vs. Ta

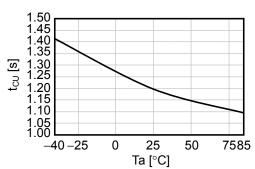


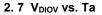
2. 2 VcL vs. Ta

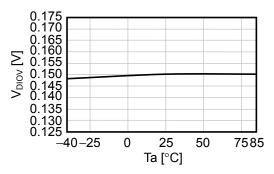


Ta [°C]

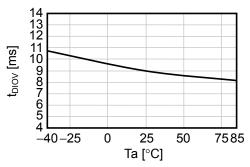
2. 5 t_{CU} vs. Ta



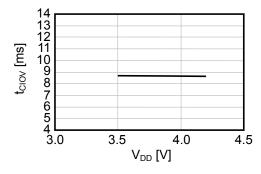




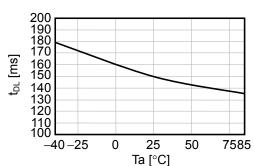




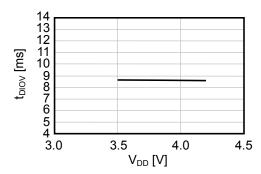
2. 11 tciov vs. VDD

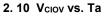


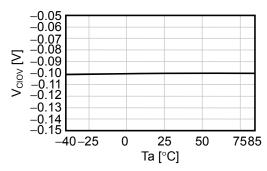




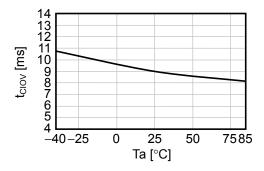


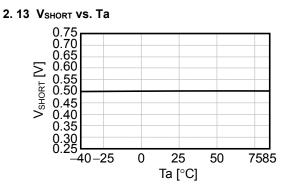




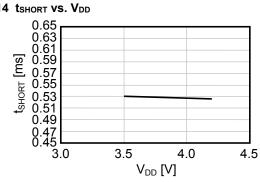


2. 12 tciov vs. Ta

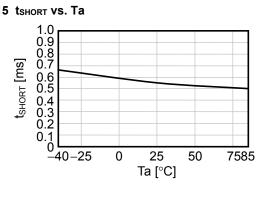




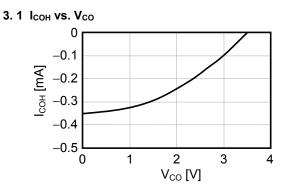


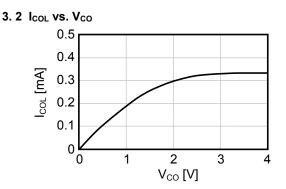


2. 15 tshort vs. Ta

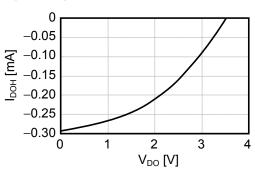


3. CO pin / DO pin

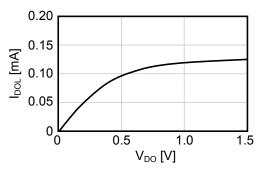






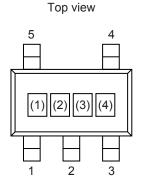


3.4 IDOL VS. VDO



Marking Specifications

1. SOT-23-5



(1) to (3): (4): Product code (refer to **Product name vs. Product code**) Lot number

Product name vs. Product code

Product Name	Pro	oduct Co	de
FIOUUCEINAITIE	(1)	(2)	(3)
S-8211CAA-M5T1x	R	Z	Α
S-8211CAB-M5T1x	R	Z	В
S-8211CAD-M5T1x	R	Z	D
S-8211CAE-M5T1x	R	Z	Е
S-8211CAF-M5T1x	R	Z	F
S-8211CAH-M5T1x	R	Z	Н
S-8211CAI-M5T1x	R	Z	-
S-8211CAJ-M5T1x	R	Z	J
S-8211CAK-M5T1x	R	Z	К
S-8211CAL-M5T1x	R	Z	L
S-8211CAM-M5T1x	R	Z	М
S-8211CAN-M5T1x	R	Z	Ν
S-8211CAO-M5T1x	R	Z	0
S-8211CAP-M5T1x	R	Z	Р
S-8211CAQ-M5T1x	R	Z	Q
S-8211CAR-M5T1x	R	Z	R
S-8211CAS-M5T1x	R	Z	S
S-8211CAT-M5T1x	R	Z	Т

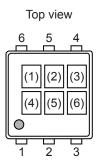
Product Name	Pro	oduct Co	ode
FIOULCEINAILIE	(1)	(2)	(3)
S-8211CAU-M5T1x	R	Z	U
S-8211CAV-M5T1x	R	Z	V
S-8211CAY-M5T1x	R	Z	Y
S-8211CAZ-M5T1x	R	Z	Z
S-8211CBV-M5T1x	R	7	V
S-8211CCD-M5T1U	R	8	D
S-8211CCJ-M5T1U	R	8	J
S-8211CCK-M5T1U	R	8	К
S-8211CCQ-M5T1U	R	8	Q
S-8211CCR-M5T1U	R	8	R
S-8211CCT-M5T1U	R	8	Т
S-8211CCV-M5T1U	R	8	V
S-8211CCW-M5T1U	R	8	W
S-8211CDB-M5T1U	R	6	В
S-8211CDD-M5T1U	R	6	D
S-8211CDG-M5T1U	R	6	G
S-8211CDJ-M5T1U	R	6	J
S-8211CDN-M5T1U	R	6	Ν

Remark 1. x: G or U

2. Please select products of environmental code = U for Sn 100%, halogen-free products.

BATTERY PROTECTION IC FOR 1-CELL PACK S-8211C Series

2. SNT-6A

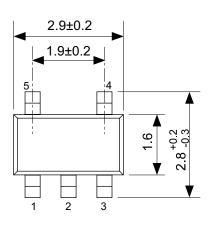


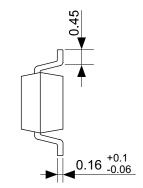
(1) to (3): (4) to (6): Product code (refer to **Product name vs. Product code**) Lot number

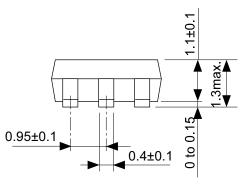
Product name vs. Product code

	Pro	oduct Co	de
Product Name	(1)	(2)	(3)
S-8211CAA-I6T1U	R	Z	Α
S-8211CAB-I6T1U	R	Z	В
S-8211CAD-I6T1U	R	Z	D
S-8211CAE-I6T1U	R	Z	E
S-8211CAF-I6T1U	R	Z	F
S-8211CAH-I6T1U	R	Z	Н
S-8211CAI-I6T1U	R	Z	-
S-8211CAJ-I6T1U	R	Z	J
S-8211CAK-I6T1U	R	Z	К
S-8211CAL-I6T1U	R	Z	L
S-8211CAM-I6T1U	R	Z	М
S-8211CAN-I6T1U	R	Z	Ν
S-8211CAO-I6T1U	R	Z	0
S-8211CAP-I6T1U	R	Z	Р
S-8211CAQ-I6T1U	R	Z	Q
S-8211CAR-I6T1U	R	Z	R
S-8211CAS-I6T1U	R	Z	S
S-8211CAT-I6T1U	R	Z Z	Т
S-8211CAU-I6T1U	R	Z	U
S-8211CAV-I6T1U	R	Z	V
S-8211CAW-I6T1U	R	Z	W
S-8211CAX-I6T1U	R	Z	Х
S-8211CAY-I6T1U	R	Z	Y
S-8211CAZ-I6T1U	R	Z	Z
S-8211CBA-I6T1U	R	7	Α
S-8211CBB-I6T1U	R	7	В
S-8211CBD-I6T1U	R	7	D
S-8211CBF-I6T1U	R	7	F
S-8211CBH-I6T1U	R	7	Н
S-8211CBJ-I6T1U	R	7	J
S-8211CBN-I6T1U	R	7	Ν
S-8211CBO-I6T1U	R	7	0

	Product Code		
Product Name	(1)	(2)	(3)
S-8211CBR-I6T1U	R	7	R
S-8211CBV-I6T1U	R	7	V
S-8211CBW-I6T1U	R	7	W
S-8211CBZ-I6T1U	R	7	Z
S-8211CCB-I6T1U	R	8	В
S-8211CCC-I6T1U	R	8	С
S-8211CCD-I6T1U	R	8	D
S-8211CCE-I6T1U	R	8	E
S-8211CCF-I6T1U	R	8	F
S-8211CCG-I6T1U	R	8	G
S-8211CCH-I6T1U	R	8	Н
S-8211CCI-I6T1U	R	8	Ι
S-8211CCJ-I6T1U	R	8	J
S-8211CCM-I6T1U	R	8	М
S-8211CCN-I6T1U	R	8	Ν
S-8211CCS-I6T1U	R	8	S
S-8211CCU-I6T1U	R	8	U
S-8211CCW-I6T1U	R	8	W
S-8211CCX-I6T1U	R	8	Х
S-8211CCY-I6T1U	R	8	Y
S-8211CCZ-I6T1U	R	8	Z
S-8211CDA-I6T1U	R	6	Α
S-8211CDC-I6T1U	R	6	С
S-8211CDE-I6T1U	R	6	F
S-8211CDF-I6T1U	R	6	E
S-8211CDH-I6T1U	R	6	Н
S-8211CDI-I6T1U	R	6	I
S-8211CDK-I6T1U	R	6	К
S-8211CDL-I6T1U	R	6	L
S-8211CDM-I6T1U	R	6	М
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S-8211CDP-I6T1U	R	6	Р

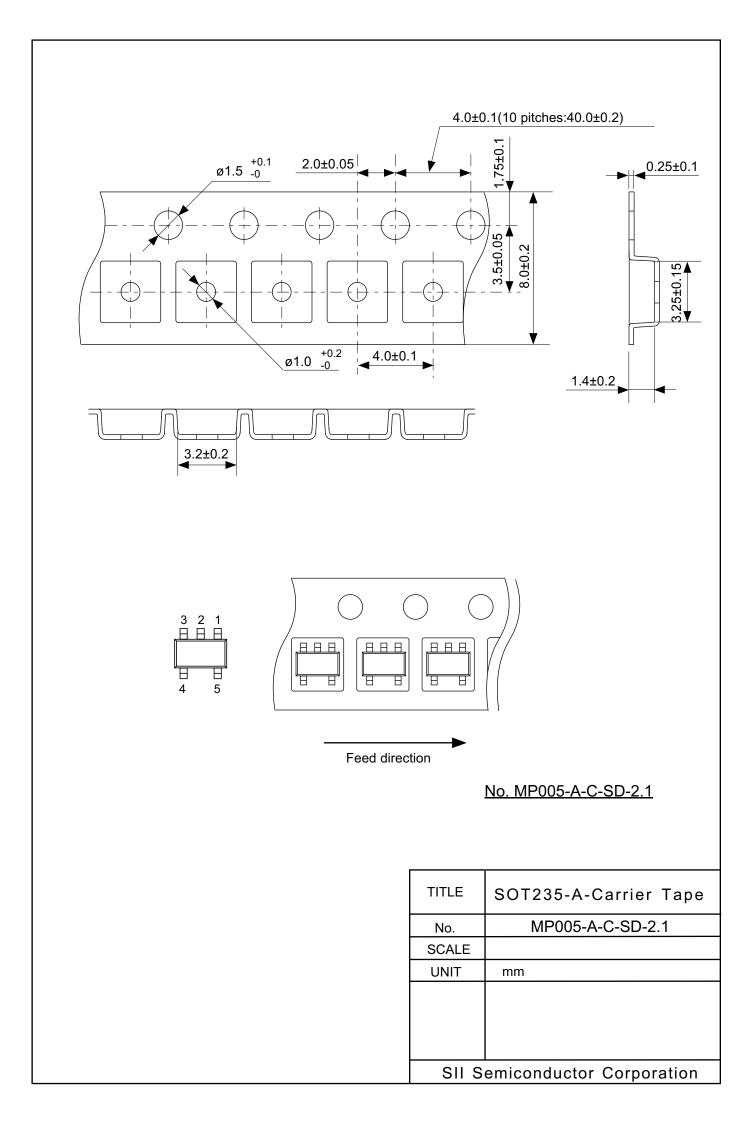


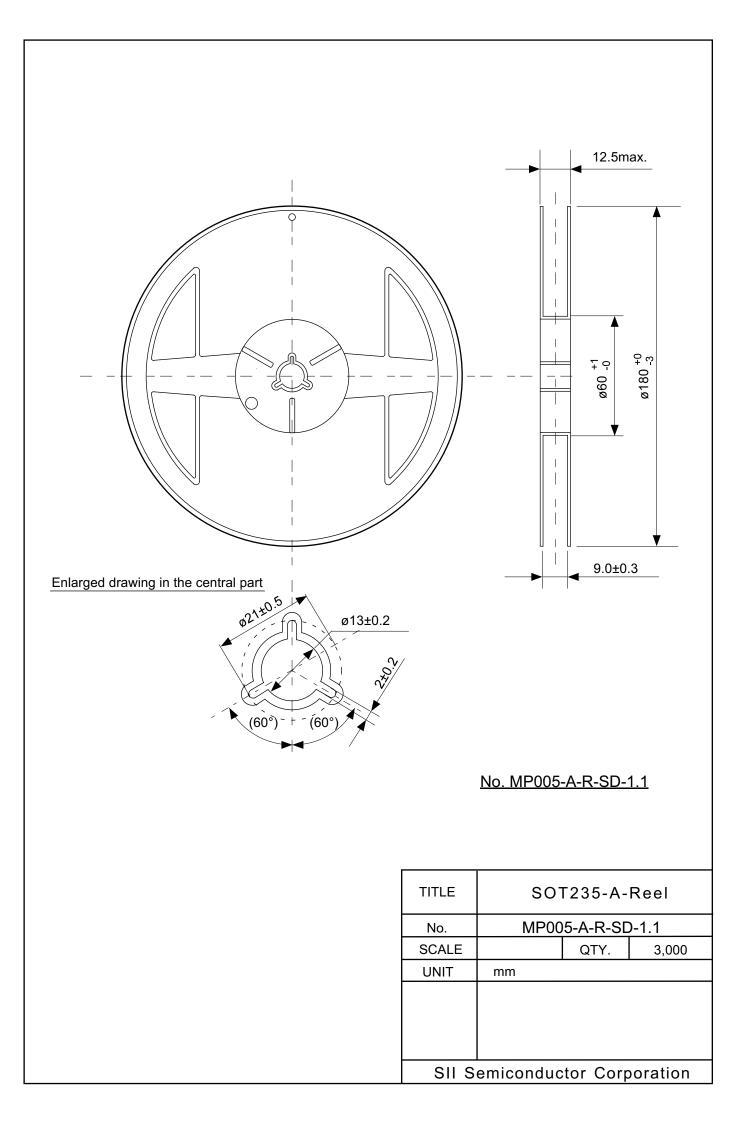


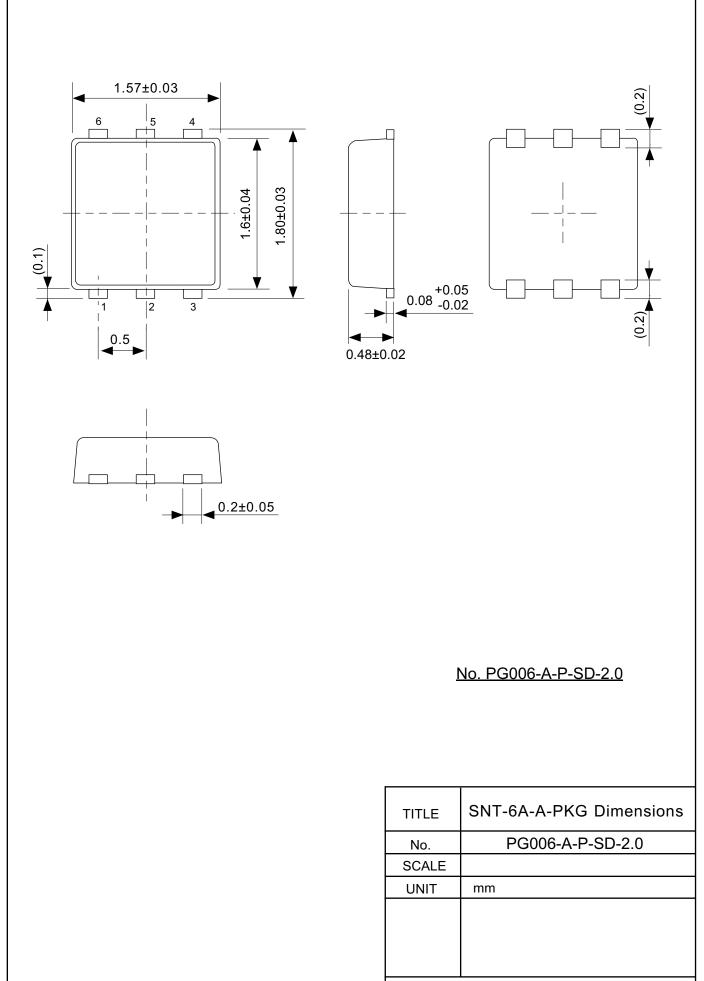


No. MP005-A-P-SD-1.2

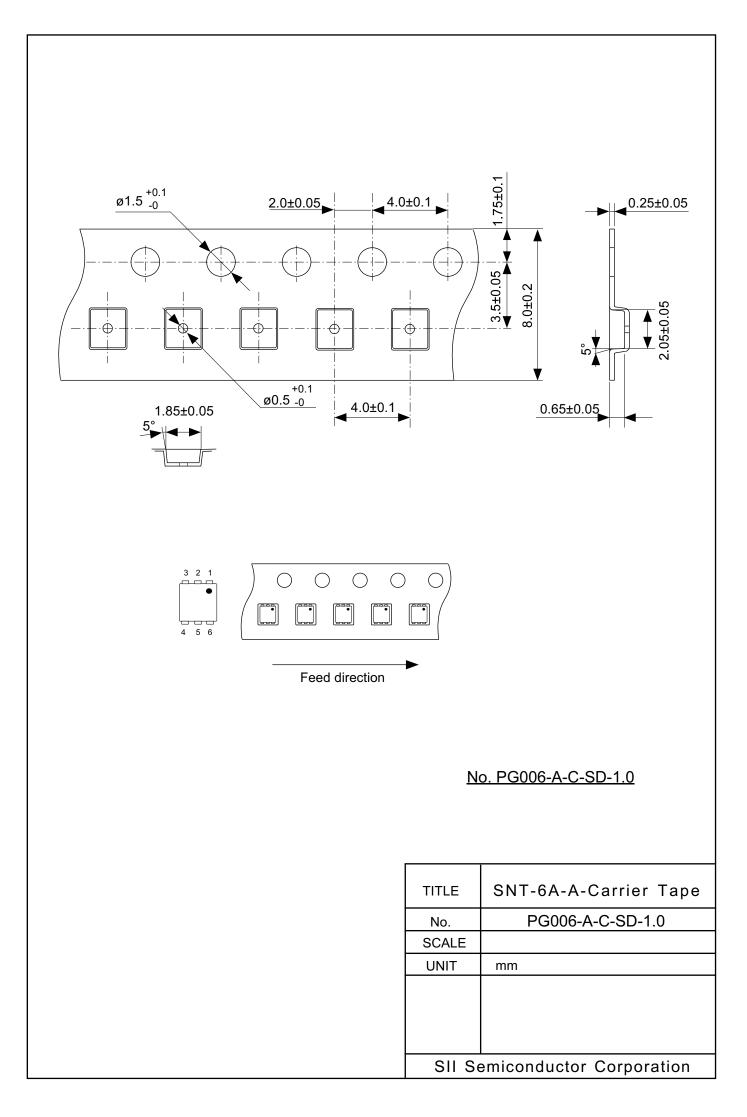
TITLE	SOT235-A-PKG Dimensions
No.	MP005-A-P-SD-1.2
SCALE	
UNIT	mm
SII S	emiconductor Corporation

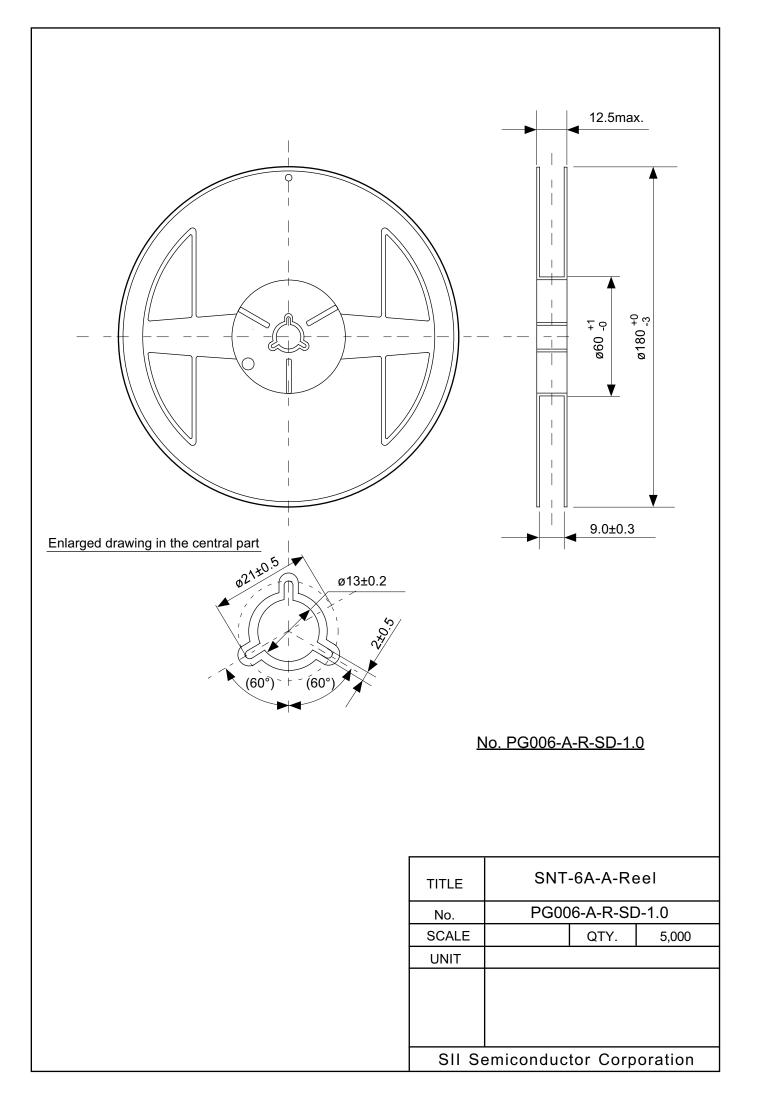


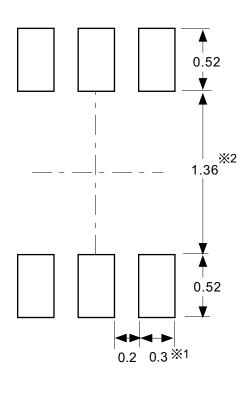




SII Semiconductor Corporation







※1. ランドパターンの幅に注意してください (0.25 mm min. / 0.30 mm typ.)。
 ※2. パッケージ中央にランドパターンを広げないでください (1.30 mm ~ 1.40 mm)。

- 注意 1. パッケージのモールド樹脂下にシルク印刷やハンダ印刷などしないでください。
 - 2. パッケージ下の配線上のソルダーレジストなどの厚みをランドパターン表面から0.03 mm 以下にしてください。
 - 3. マスク開ロサイズと開口位置はランドパターンと合わせてください。
 - 4. 詳細は "SNTパッケージ活用の手引き" を参照してください。

%1. Pay attention to the land pattern width (0.25 mm min. / 0.30 mm typ.).

X2. Do not widen the land pattern to the center of the package (1.30 mm ~ 1.40 mm).

- Caution 1. Do not do silkscreen printing and solder printing under the mold resin of the package.
 2. The thickness of the solder resist on the wire pattern under the package should be 0.03 mm or less from the land pattern surface.
 - 3. Match the mask aperture size and aperture position with the land pattern.
 - 4. Refer to "SNT Package User's Guide" for details.
- ※1. 请注意焊盘模式的宽度 (0.25 mm min. / 0.30 mm typ.)。
- ※2. 请勿向封装中间扩展焊盘模式 (1.30 mm ~ 1.40 mm)。
- 注意 1. 请勿在树脂型封装的下面印刷丝网、焊锡。
 - 2. 在封装下、布线上的阻焊膜厚度 (从焊盘模式表面起) 请控制在 0.03 mm 以下。
 - 3. 钢网的开口尺寸和开口位置请与焊盘模式对齐。
 - 4. 详细内容请参阅 "SNT 封装的应用指南"。

TITLE	SNT-6A-A -Land Recommendation	
No.	PG006-A-L-SD-4.1	
SCALE		
UNIT	mm	
	miconductor Corporation	
SII Semiconductor Corporation		

No. PG006-A-L-SD-4.1

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- 1. All the information described herein (product data, specifications, figures, tables, programs, algorithms and application circuit examples, etc.) is current as of publishing date of this document and is subject to change without notice.
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Prior consultation with our sales office is required when considering the above uses.

SII Semiconductor Corporation is not responsible for damages caused by unauthorized or unspecified use of our products.

9. Semiconductor products may fail or malfunction with some probability.

The user of these products should therefore take responsibility to give thorough consideration to safety design including redundancy, fire spread prevention measures, and malfunction prevention to prevent accidents causing injury or death, fires and social damage, etc. that may ensue from the products' failure or malfunction. The entire system must be sufficiently evaluated and applied on customer's own responsibility.

- 10. The products described herein are not designed to be radiation-proof. The necessary radiation measures should be taken in the product design by the customer depending on the intended use.
- 11. The products described herein do not affect human health under normal use. However, they contain chemical substances and heavy metals and should therefore not be put in the mouth. The fracture surfaces of wafers and chips may be sharp. Take care when handling these with the bare hands to prevent injuries, etc.
- 12. When disposing of the products described herein, comply with the laws and ordinances of the country or region where they are used.
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1.0-2016.01



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 IFM201-01UK-E
 CAPM347B-E

 LB1256-E
 SLP-1RLB
 PW-C0725-W1-K
 LTP9247B-C448-E
 401-PLATEN
 IF2301-01B
 IF3002-01B
 KPU-S447S-11H-E
 DPU-D3-00A-E

 X1G004481003100
 X1E0000210477
 SG-8018CE-29.500000MHz-TJHPA
 SG-8018CB-55.296000MHz-TJHSA
 SG-8018CB-48.000000MHz-TJHPA

 SG-8018CE-10.485760MHz-TJHPA
 SG-8018CB-33.300000MHz-TJHPA
 SG-8018CB-40.000000MHz-TJHPA
 SG-8018CB-54.000000MHz-TJHSA

 SG-8018CE-10.485760MHz-TJHPA
 SG-8018CB-33.300000MHz-TJHPA
 SG-8018CB-40.000000MHz-TJHPA
 SG-8018CB-54.000000MHz-TJHSA

 SG-8010000MHz-TJHSA
 SG-8018CE-54.000000MHz-TJHSA
 SG-8002CA-10.000000MHz-PCM
 SG-8002CA-62.500000MHz-PCM

 X1G004281001111
 X1G004261012611
 X1G004281010311
 X1G004261012011
 X1G004241002811
 SG-9101CA 32.768MHz D05PHAAA

 SG-9101CE
 20.000MHz
 C20PHAAA
 SLP-TRAY650
 RP-B10-U11JW1-03
 APU-9247-C01P-E
 CAPD347A-E
 DPU-S245-BLUETOOTH

 SLP-2RLH
 RP-E11-K3FJ1-U1C3
 RP-E10-K3FJ1-U1C3
 ACU2324C-A-E
 SG-8018CG-106.666666MHz-TJHPA
 SG-8018CB

 29.9711000MHz-TJHPA
 SG-8002CA-14.745600MH